

2016 Spring

**“Advanced Physical Metallurgy”
- Bulk Metallic Glasses -**

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Q1: Theories for the glass transition

Theories for the glass transition

A. Thermodynamic phase transition

- Glass transition

H, V, S : continuous

C_p, α_T, K_T : discontinuous

→ by thermodynamic origin, 2nd order transition

→ In fact, it appears on some evidences that the glass transition is **not a simple second-order phase transition.**

$$R = \frac{\Delta\kappa_T \Delta C_P}{TV(\Delta\alpha_T)^2} \neq 1$$

B. Entropy

- Heat capacity → dramatic change at T_g
- Description of glass transition by entropy (Kauzmann)

$S = \int C_P d \ln T$ → The slow cooling rate, the lower T_g → T_K or T_g^0

→ Measurement of Kauzmann temp. is almost impossible.

(∵ very slow cooling rate → longer relaxation time → crystallization)

Theories for the glass transition

C. Relaxation behavior

Below glass transition: **frozen-in liquid**

- glass transition is observed when the **experimental time scale** (1) becomes comparable with the **time scale for atom/molecule arrangement** (2)
- **If (1) > (2) ⇒ liquid // (1)~(2) ⇒ glass transition // (1) < (2) ⇒ glass**

(A concept of glass transition based on kinetic view point)

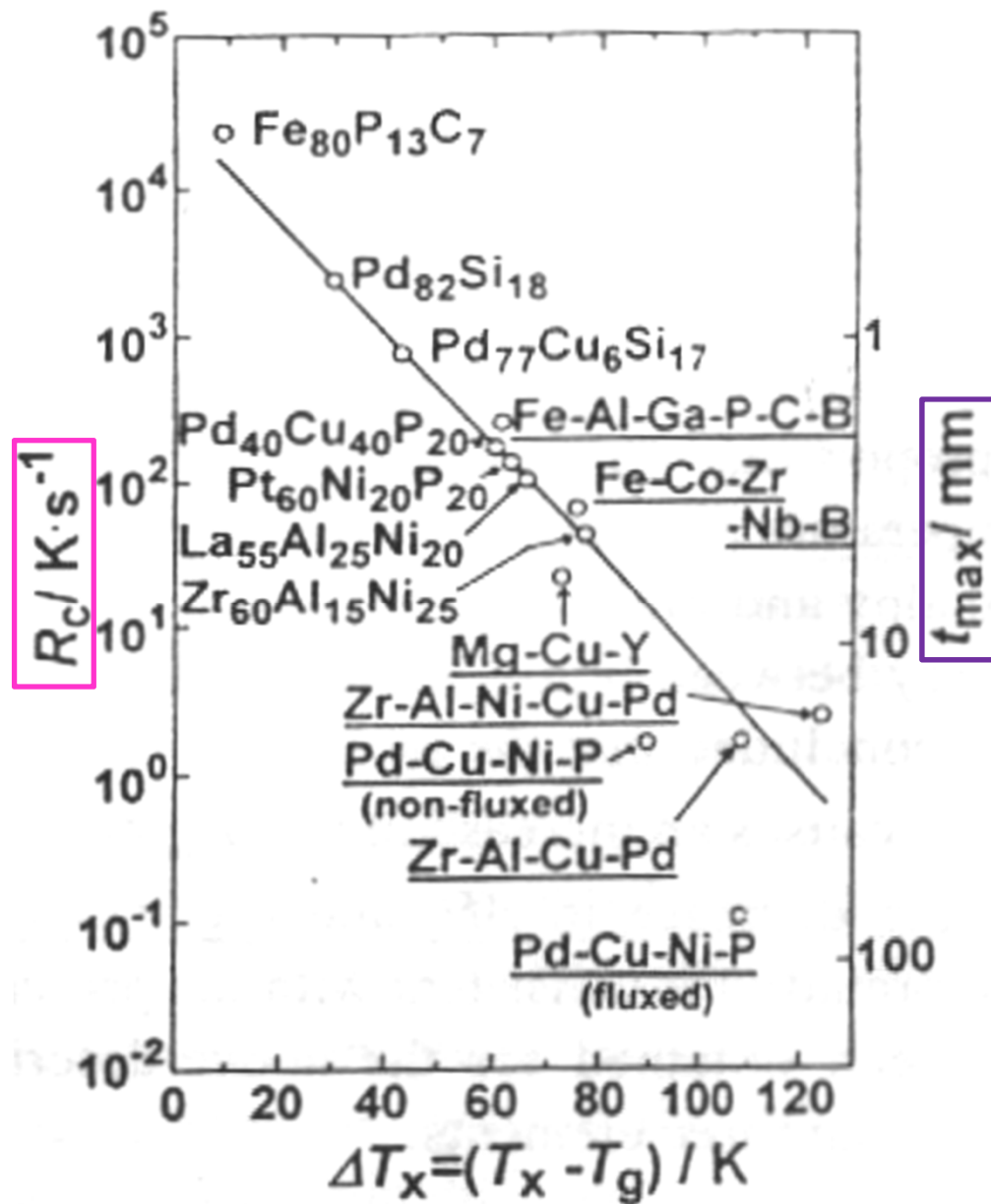
: property of liquid-like structure suddenly changes to that of solid-like structure

d. viscosity

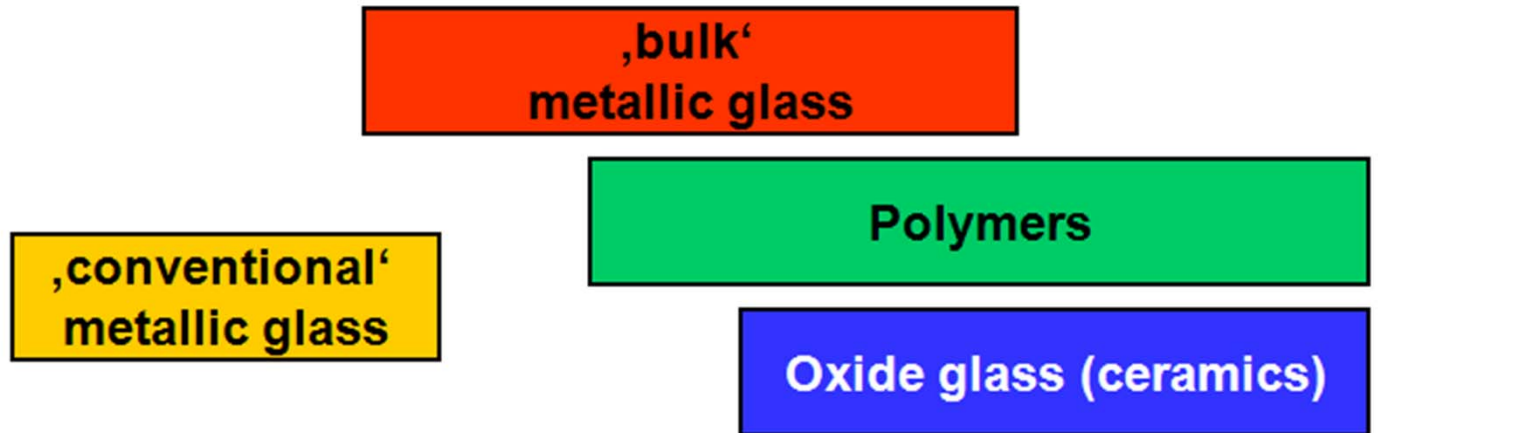
- **Viscosity (10^{15} centiPoise = 10^{12-13} Pa s) at T_g**
- most glass forming liquid exhibit high viscosity.
- In glass transition region, viscosity suddenly changes. (fragile glass)
 - Fragility concept: Strong vs Fragile
- **Viscous flow** → Several atomistic model
 - absolute rate model
 - free volume model
 - excess entropy model

Q2: Glass formation

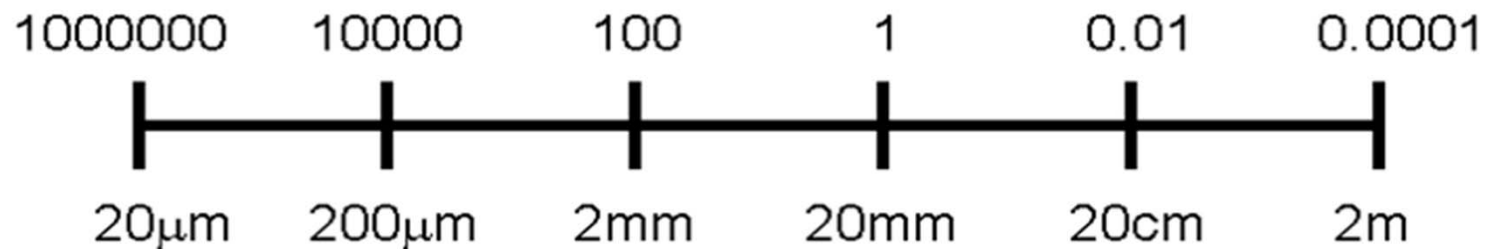
Critical cooling rate is inversely proportional to the diameter of ingot.



Critical cooling rates and thicknesses for different materials



Critical cooling rate K/s



Max. thickness

Critical Cooling Rates for Various Liquids

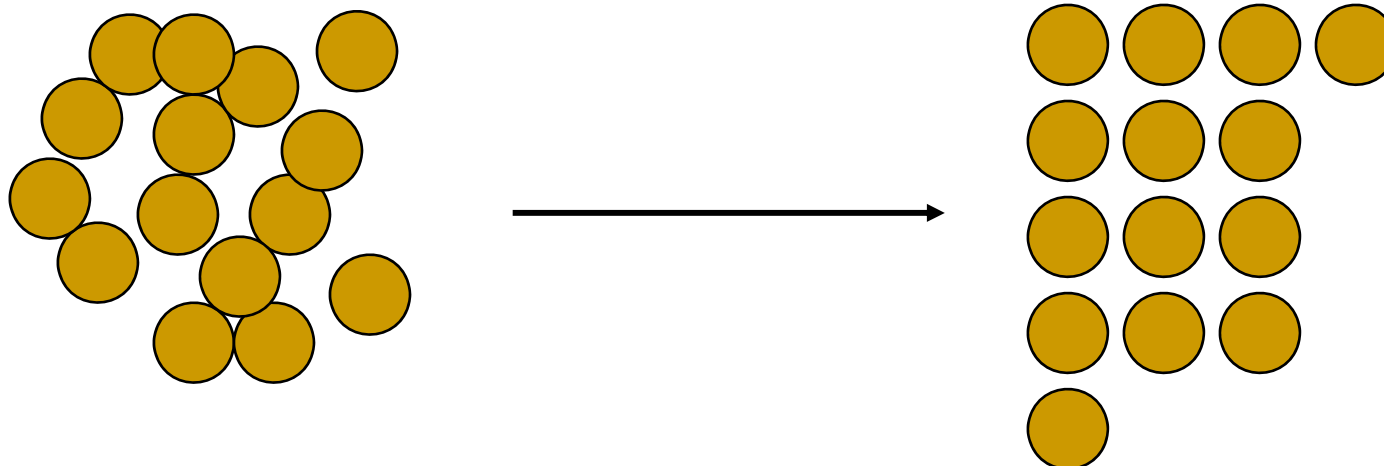
Table 3-5. Examples of Critical Cooling Rates ($^{\circ}\text{C}/\text{s}$) for Glass Formation

| Material | Homogeneous nucleation | Heterogeneous nucleation contact angle (deg) | | |
|--|---------------------------|---|--------------------|--------------------|
| | | 100 | 60 | 40 |
| SiO_2 glass ^a | 9×10^{-6} | 10^{-5} | 8×10^{-3} | 2×10^{-1} |
| GeO_2 glass ^a | 3×10^{-3} | 3×10^3 | 1 | 20 |
| $\text{Na}_2\text{O} \cdot 2\text{SiO}_2$ glass ^a | 6×10^{-3} | 8×10^{-3} | 10 | $3 \times 10^{+2}$ |
| Salol | 10 | | | |
| Water | 10^7 | | | |
| Ag | 10^{10} | | | |
| Typical metal ^a | 9×10^8 | 9×10^9 | 10^{10} | 5×10^{10} |

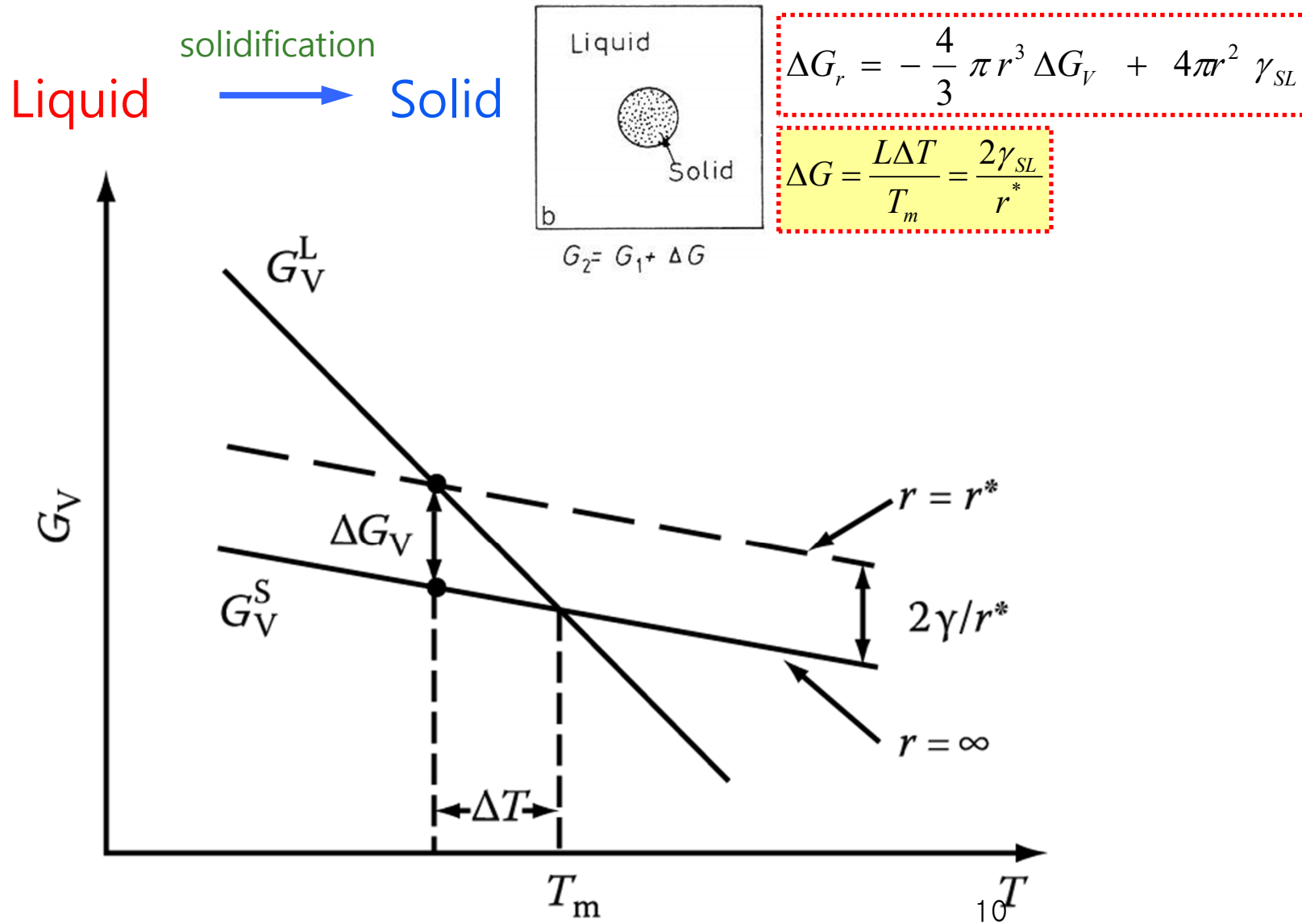
^a After P. I. K. Onorato and D. R. Uhlmann, *J. Non-Cryst. Sol.*, 22(2), 367–378 (1976).

Nucleation and Growth Rates Control R_c

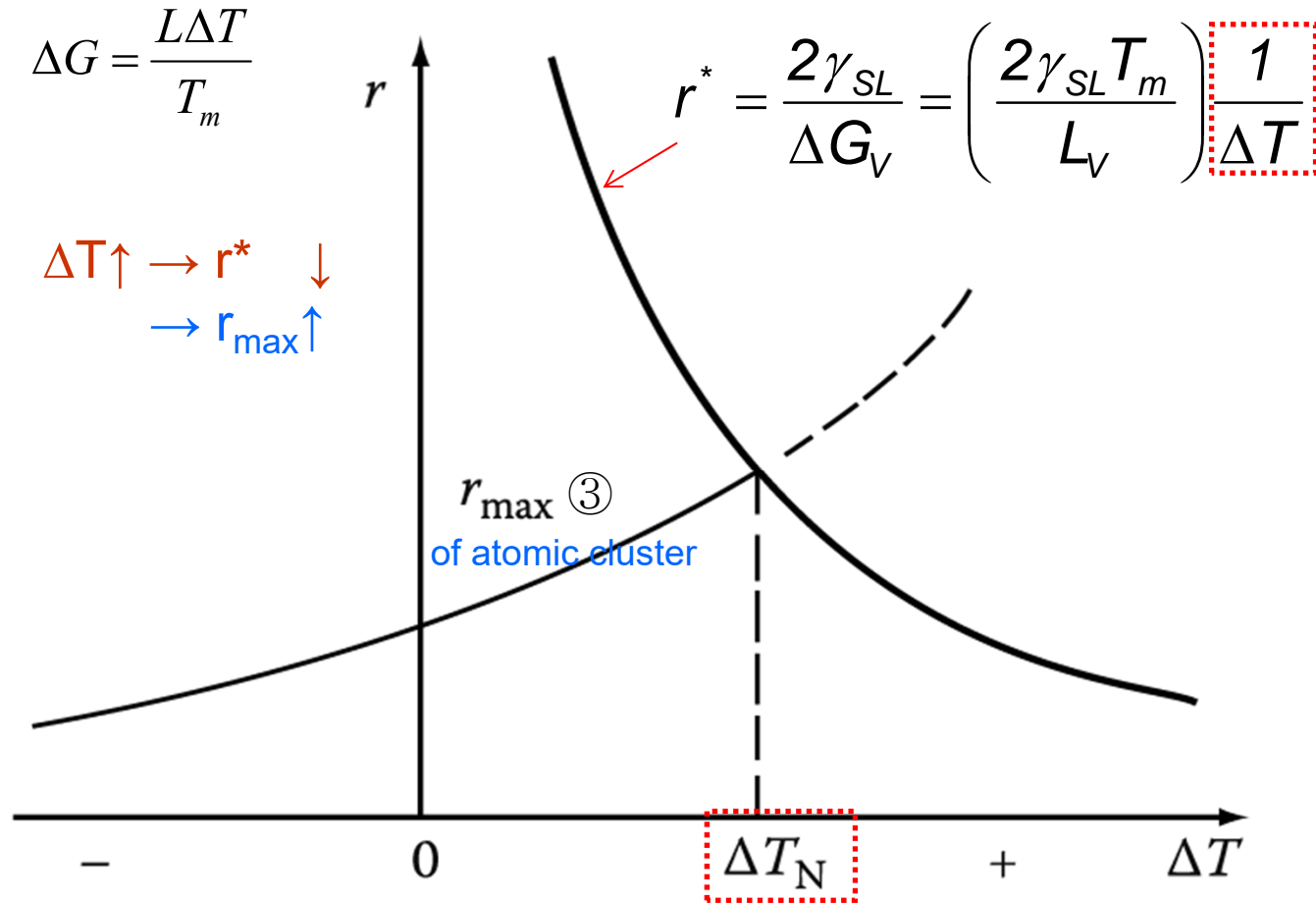
- Nucleation, the first step...
- First process is for microscopic clusters (nuclei) of atoms or ions to form
 - Nuclei possess the **beginnings** of the structure of the crystal
 - **Only limited diffusion** is necessary
 - **Thermodynamic driving force for crystallization** must be present



1.2.3 Driving force for solidification



The creation of a critical nucleus ~ thermally activated process



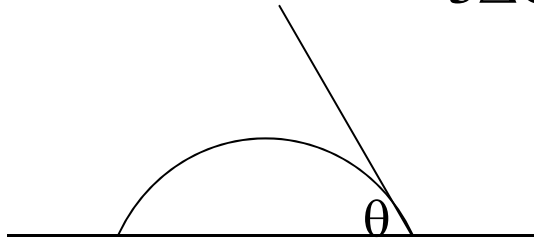
ΔT_N is the critical undercooling for homogeneous nucleation.

Fig. 4.5 The variation of r^* and r_{\max} with undercooling ΔT

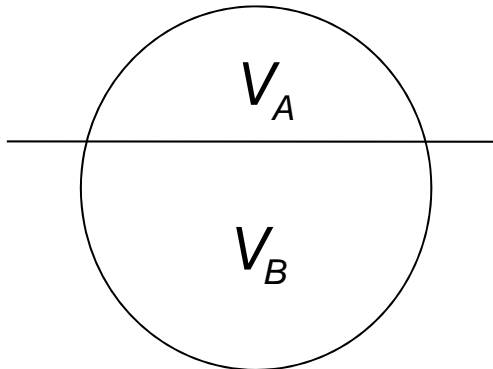
The number of clusters with r^* at $\Delta T < \Delta T_N$ is negligible.

Barrier of Heterogeneous Nucleation

$$\Delta G^* = \frac{16\pi\gamma_{SL}^3}{3\Delta G_V^2} \cdot S(\theta) = \frac{16\pi\gamma_{SL}^3}{3\Delta G_V^2} \cdot \frac{(2 - 3\cos\theta + \cos^3\theta)}{4}$$



$$\Delta G_{het}^* = S(\theta)\Delta G_{hom}^*$$



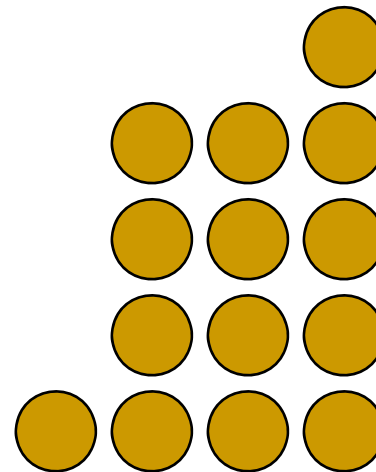
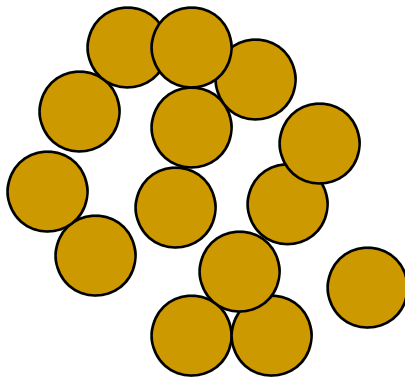
$$\Delta G_{sub}^* = \Delta G_{homo}^* \left(\frac{2 - 3\cos\theta + \cos^3\theta}{4} \right)$$

$$\frac{V_A}{V_A + V_B} = \frac{2 - 3\cos\theta + \cos^3\theta}{4} = S(\theta)$$

How about the nucleation at the crevice or at the edge?

Growth of crystals from nuclei

- Growth processes then enlarge existing nuclei
- **Smallest nuclei** often **redissolve**
- **Larger nuclei** can get **larger**
- **Thermodynamics** favors the formation of **larger nuclei**



Kinetic Roughening

Rough interface - Ideal Growth → diffusion-controlled → dendritic growth

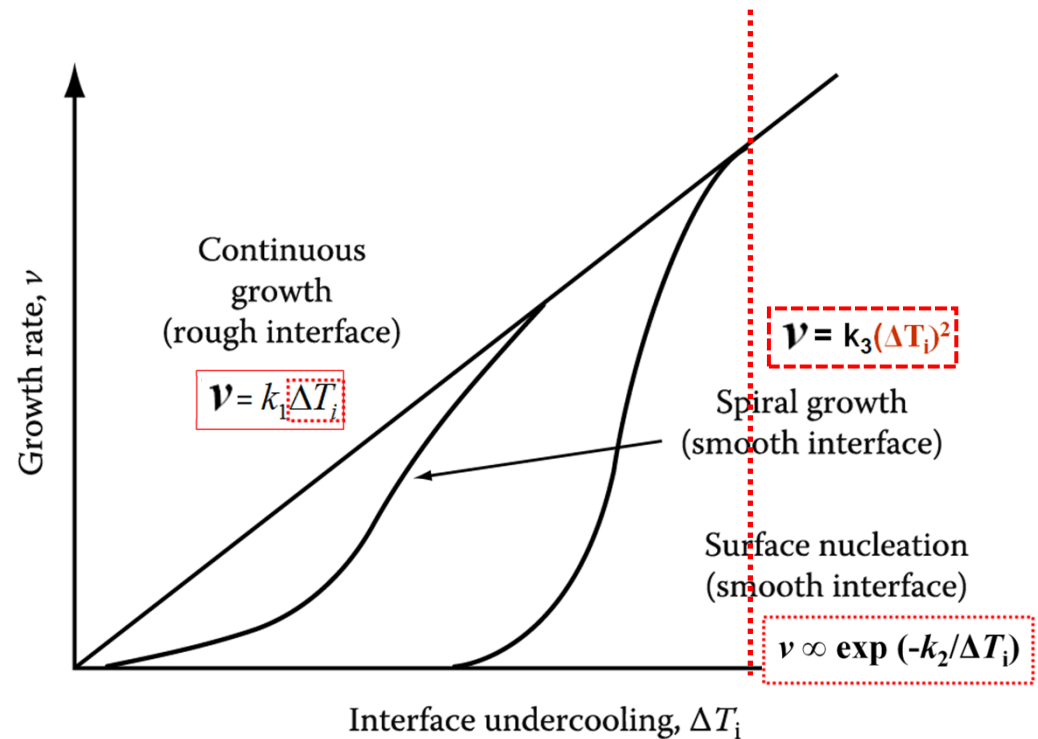
Smooth interface - Growth by Screw Dislocation
Growth by 2-D Nucleation

Small ΔT → “feather” type of growth ↔ Large ΔT → cellular/dendritic growth

The growth rate of the singular interface cannot be higher than ideal growth rate.

When the growth rate of the singular interface is high enough, it follows the ideal growth rate like a rough interface.

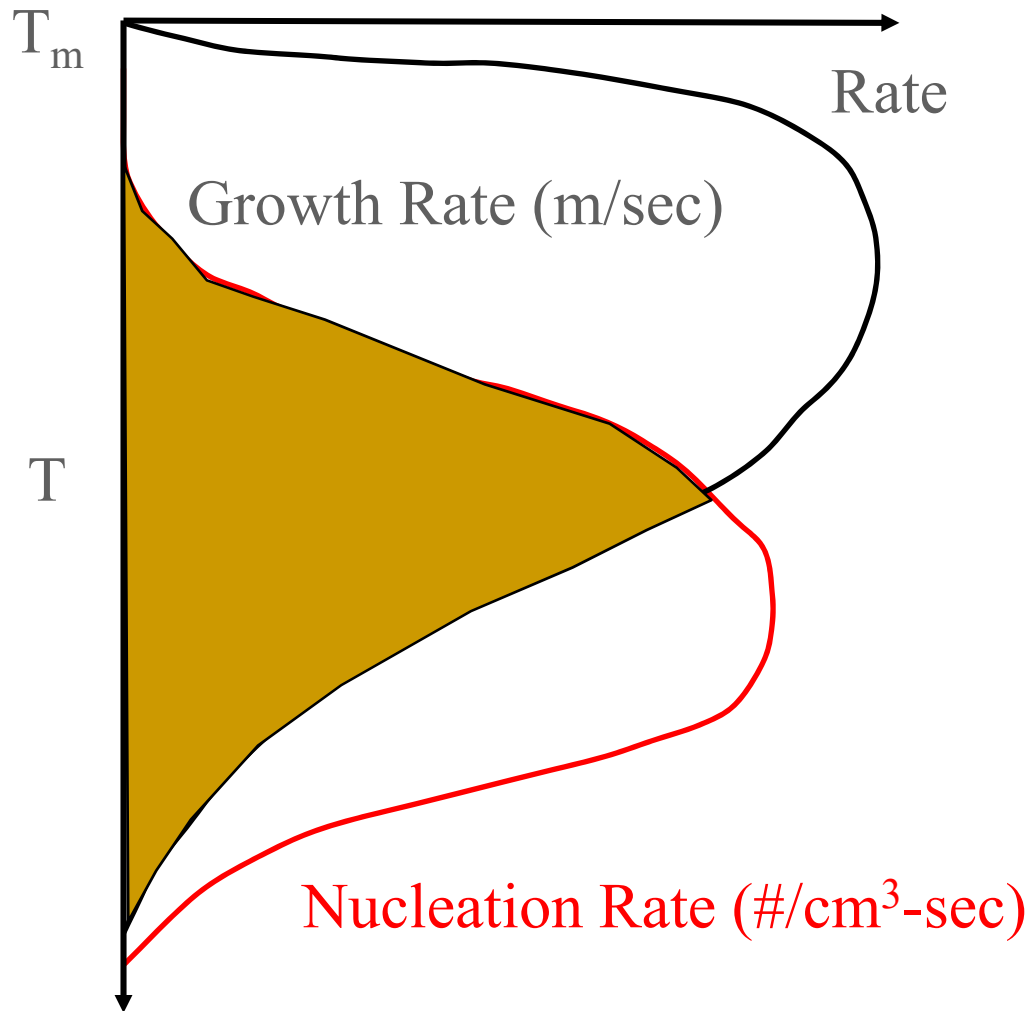
→ kinetic roughening



Nucleation and Growth Control R_c

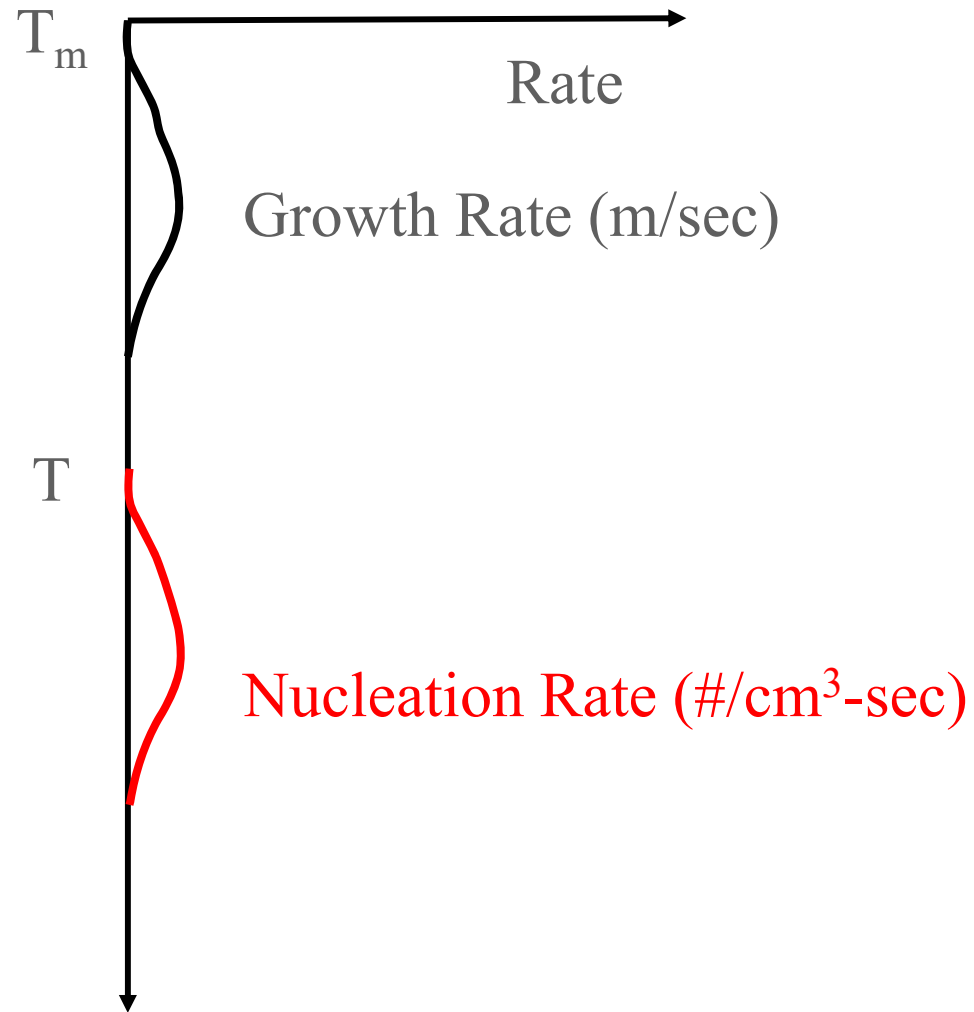
- Poor glass formers:
 - Liquids which quickly form large numbers of nuclei close to T_m
 - That grow very quickly
- Good glass formers
 - Liquids that are sluggish to form nuclei even far below T_m
 - That grow very slowly

Nucleation and Growth Rates – Poor Glass Formers



- Strong overlap of growth and nucleation rates
- Nucleation rate is high
- Growth rate is high
- Both are high at the same temperature

Nucleation and Growth Rates – Good Glass Formers



- No overlap of growth and nucleation rates
- Nucleation rate is small
- Growth rate is small
- At any one temperature one of the two is zero

Q3: Classical Nucleation Theory-TTT diagram

Nucleation Rate Theory

- Rate at which atoms or ions in the liquid organize into microscopic crystals, nuclei
- $I =$ **number of nuclei** formed per **unit time** per **unit volume of liquid**
- Nucleation Rate (I) \propto number density of atoms x fastest motion possible x thermodynamic probability of formation x diffusion probability

Nucleation Rate Theory

$$I = n \nu \exp(-NW^*/RT) \exp(-\Delta E_D/RT)$$

Number density Fastest motion Thermodynamic probability Diffusion probability

n = number density of atoms, molecules, or formula units per unit volume

= ρN /Atomic, molecular, formula weight

ν = vibration frequency $\sim 10^{13} \text{ sec}^{-1}$

N = Avogadro's number

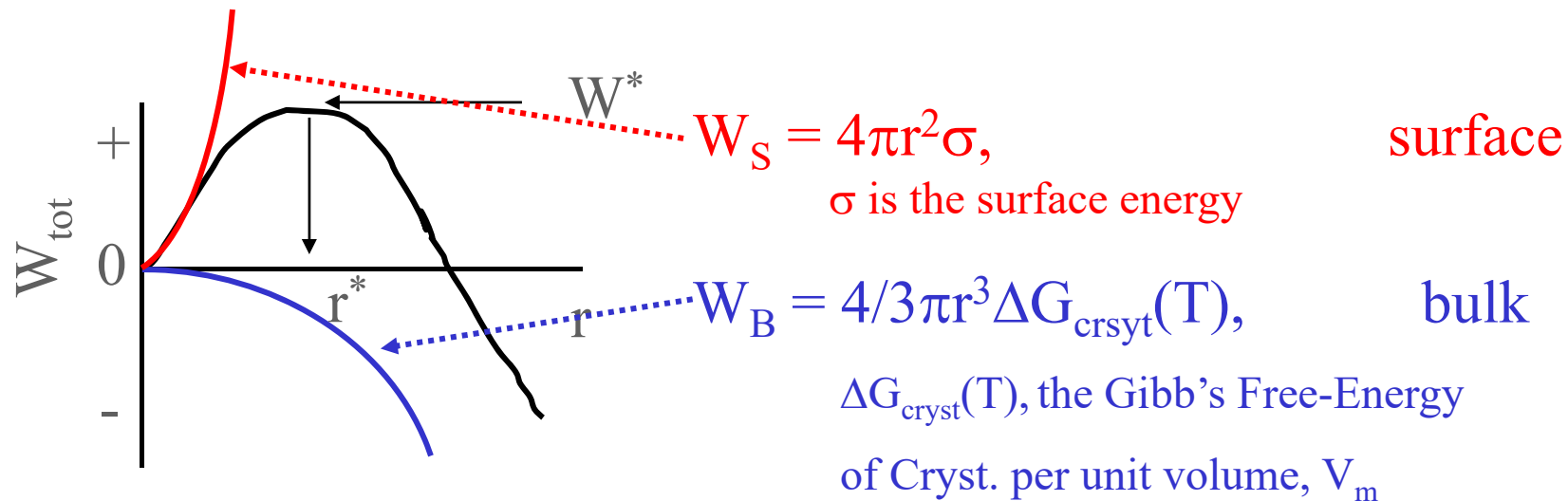
= 6.023×10^{23} atoms/mole

W^* = thermodynamic energy barrier to form nuclei

ΔE_D = diffusion energy barrier to form nuclei

\sim viscosity activation energy

Nucleation Rate – Thermodynamic barrier W^*

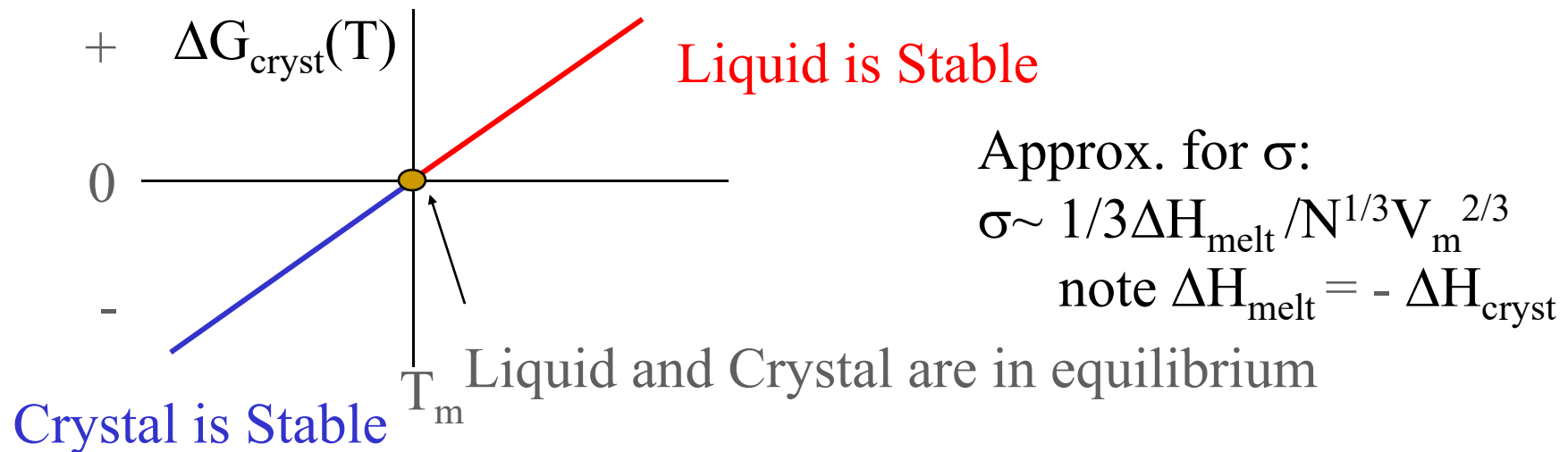


$$W_{\text{tot}} = W_S + W_B$$

- At r^* , $(\partial W(r) / \partial r)_{r=r^*} = 0$
- $r^* = -2\sigma / \Delta G_{\text{cryst}}(T)$
- $W(r^*) \equiv W^* = 16\pi \sigma^3 / 3(\Delta G_{\text{cryst}}(T))^2$

Nucleation Rate $I(T)$

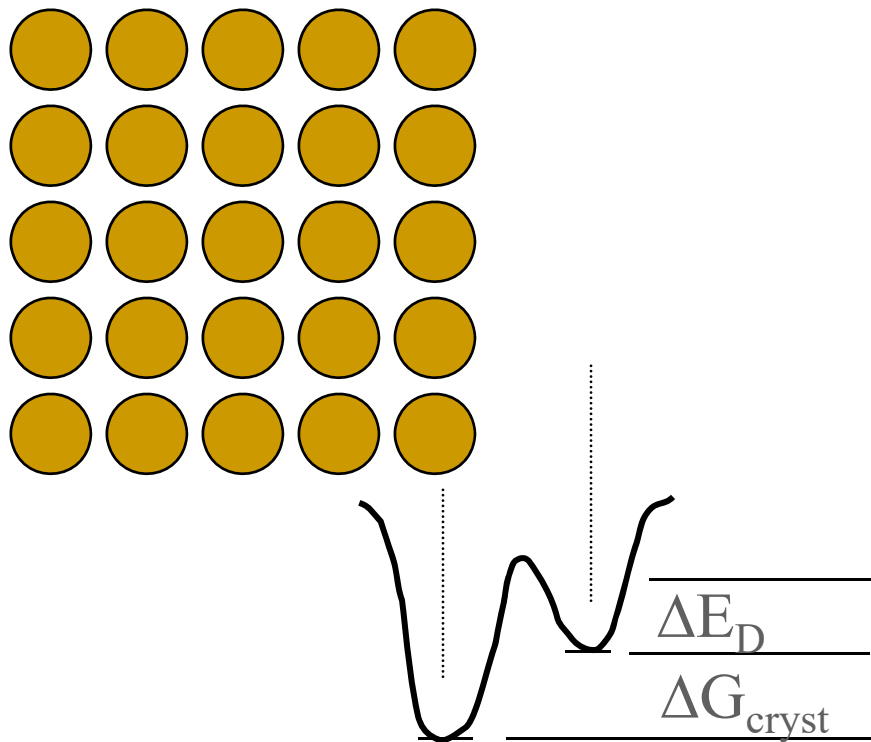
- $I = n v \exp(-N \frac{16\pi \sigma^3}{3(\Delta G_{cryst}(T))^2} / RT) \exp(-\Delta E_D / RT)$
- $\Delta G_{cryst}(T) = \Delta H_{cryst}(T_m)(1 - T/T_m)/V_m \equiv \Delta H_{cryst}(T_m)(\Delta T_m/T_m)$



$$I = n v \exp \left\{ \left(\frac{16\pi \Delta H_{cryst}}{81RT} \right) \left(\frac{T_m}{\Delta T} \right)^2 \right\} \exp \left\{ \frac{-\Delta E_D}{RT} \right\}$$

Growth Rates - $\mu(T)$

- Crystal growth requires
 - Diffusion to the nuclei surface
 - Crystallization onto the exposed crystal lattice



$$v_{l \rightarrow c} = v \exp(-\Delta E_D / RT)$$

$$v_{c \rightarrow l} = v \exp(-(\Delta E_D - \Delta G_{cryst}) / RT)$$

$$v_{net} = v_{l \rightarrow c} - v_{c \rightarrow l} =$$

$$v \exp(-\Delta E_D / RT) -$$

$$v \exp(-(\Delta E_D - \Delta G_{cryst}) / RT)$$

$$\mu = a v_{net} = a v \exp(-\Delta E_D / RT) \times (1 - \exp(\Delta G_{cryst} / RT))$$

Growth Rates - $\mu(T)$

Diffusion coefficient, D

$$D(T) = a^2 \nu \exp\left[\frac{-\Delta E_D}{RT}\right] = \left(\frac{fRT}{3N\pi a \eta(T)}\right)$$

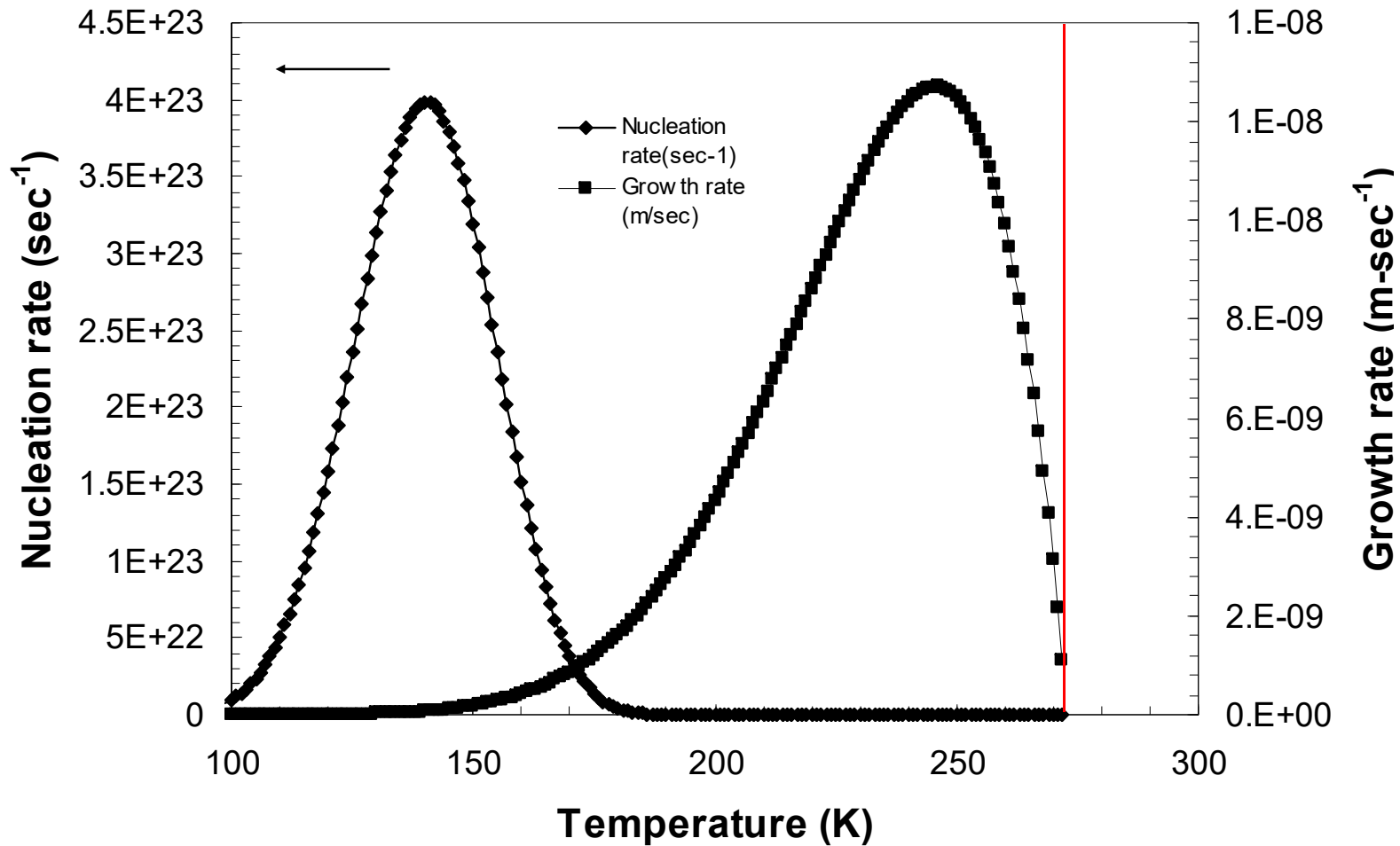
Stokes-Einstein relation between D and η

Hence:

$$\mu(T) = \left(\frac{fRT}{3N\pi a^2 \eta(T)}\right) \left(1 - \exp\left[\left(\frac{\Delta H_m}{RT}\right)\left(\frac{\Delta T}{T_m}\right)\right]\right)$$

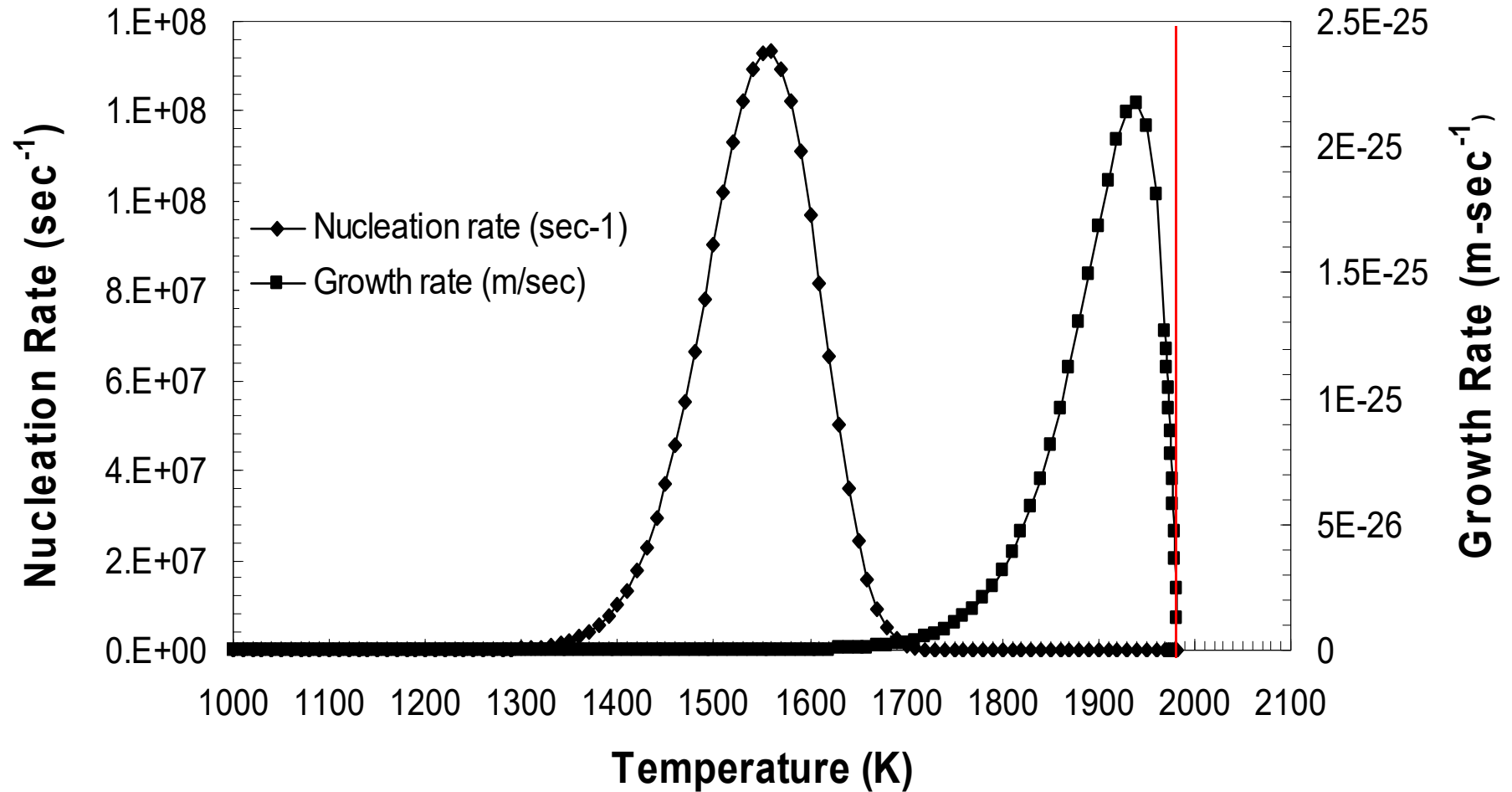
Nucleation and Growth Rates

Nucleation and Growth Rates for Water



Nucleation and Growth Rates

Nucleation and Growth for Silica



Time-Temperature-Transformation Curves (TTT)

- How much time does it take at any one temperature for a given fraction of the liquid to transform (nucleate and grow) into a crystal?

- $f(t, T) \sim \pi I(T) \mu(T)^3 t^4 / 3$

where f is the fractional volume of crystals formed, typically taken to be 10^{-6} , a barely observable crystal volume.

Nucleation rates

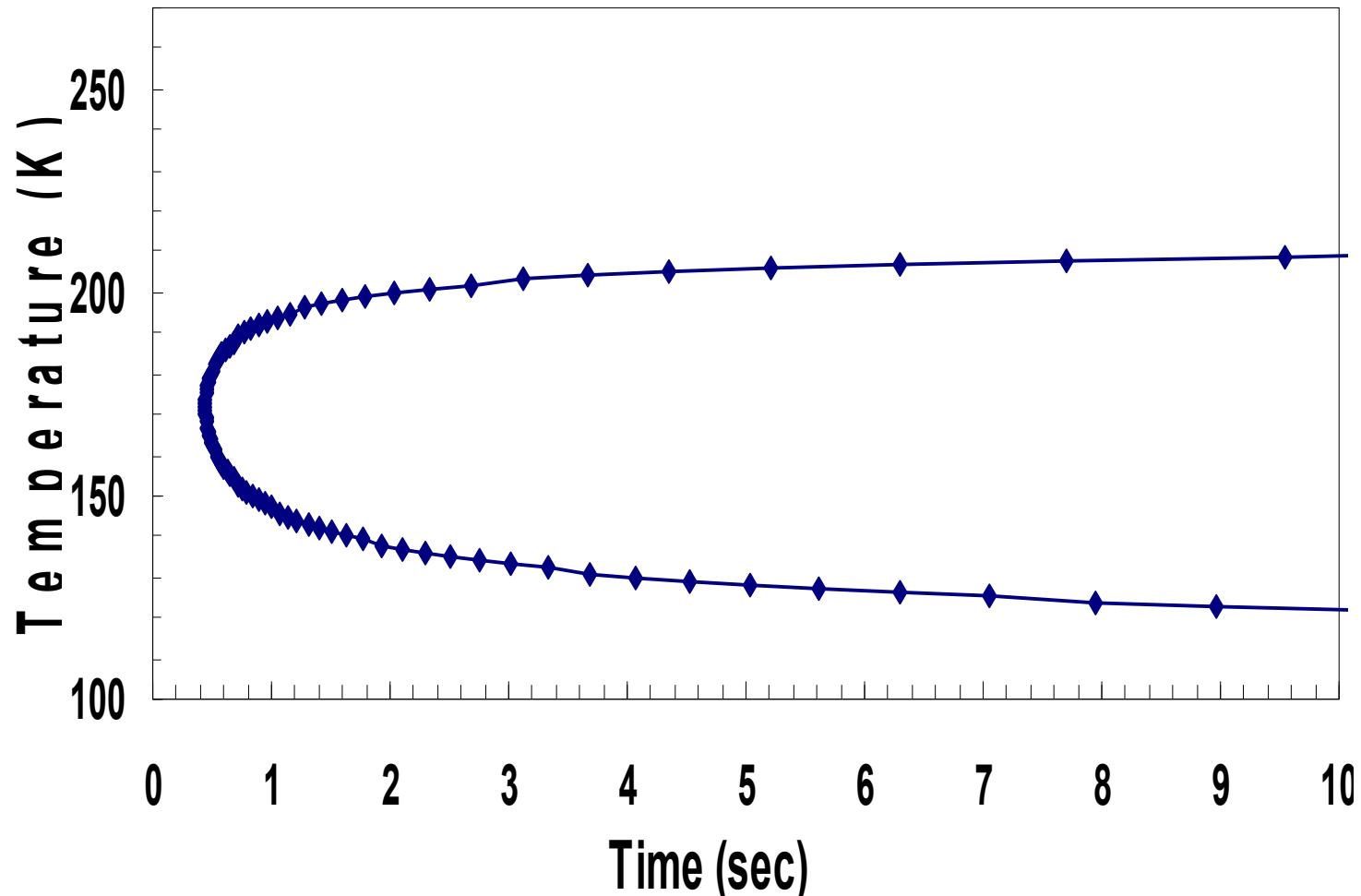
$$I = n \nu \exp\left\{\left(\frac{16\pi\Delta H_{cryst}}{81RT}\right)\left(\frac{T_m}{\Delta T}\right)^2\right\} \exp\left\{\frac{-\Delta E_D}{RT}\right\}$$

Growth rates

$$\mu(T) = \left(\frac{fRT}{3N\pi\alpha^2\eta(T)}\right) \left(1 - \exp\left[\left(\frac{\Delta H_m}{RT}\right)\left(\frac{\Delta T}{T_m}\right)\right]\right)$$

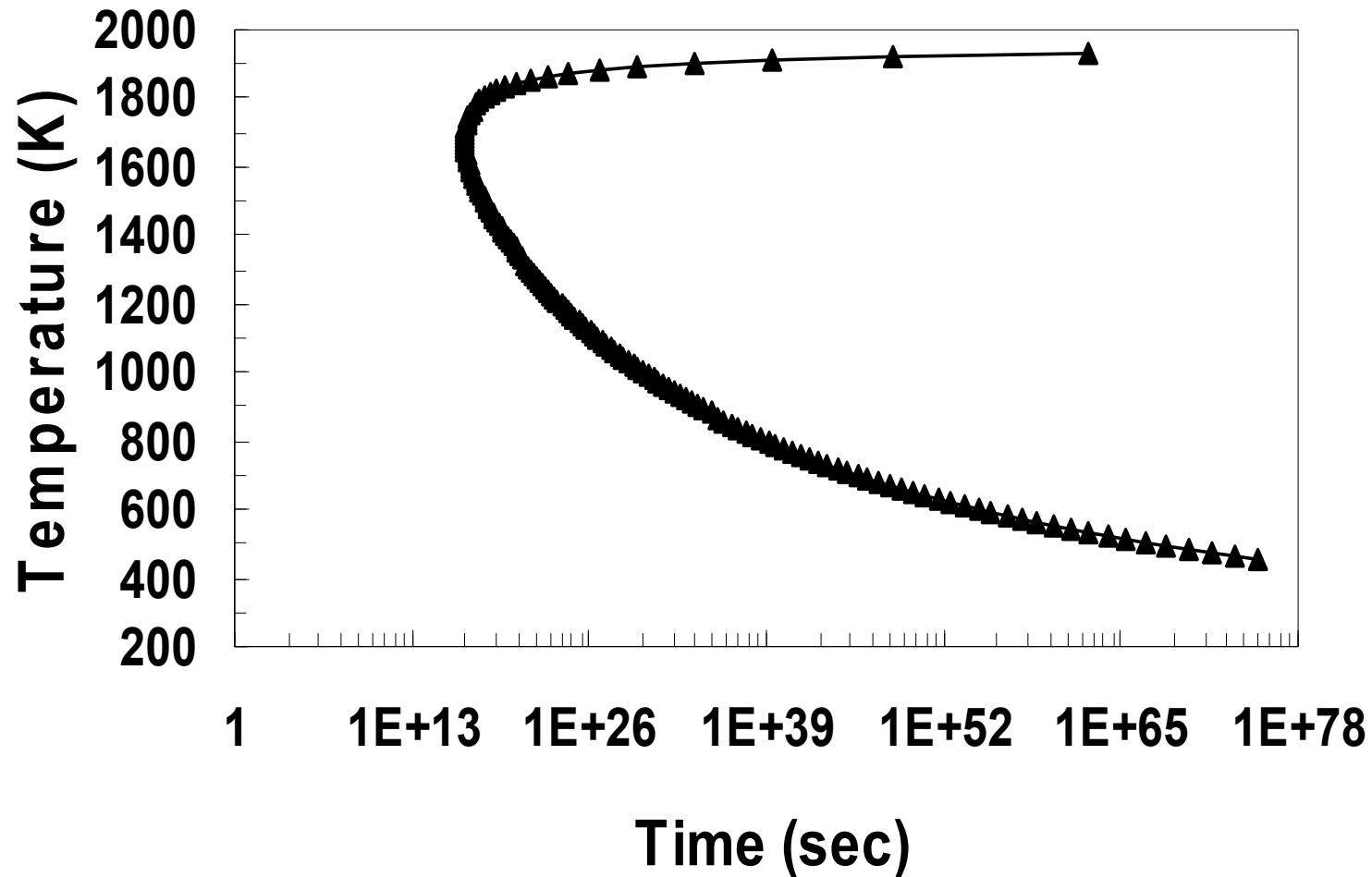
Time Transformation Curves for Water

T-T-T Curve for water

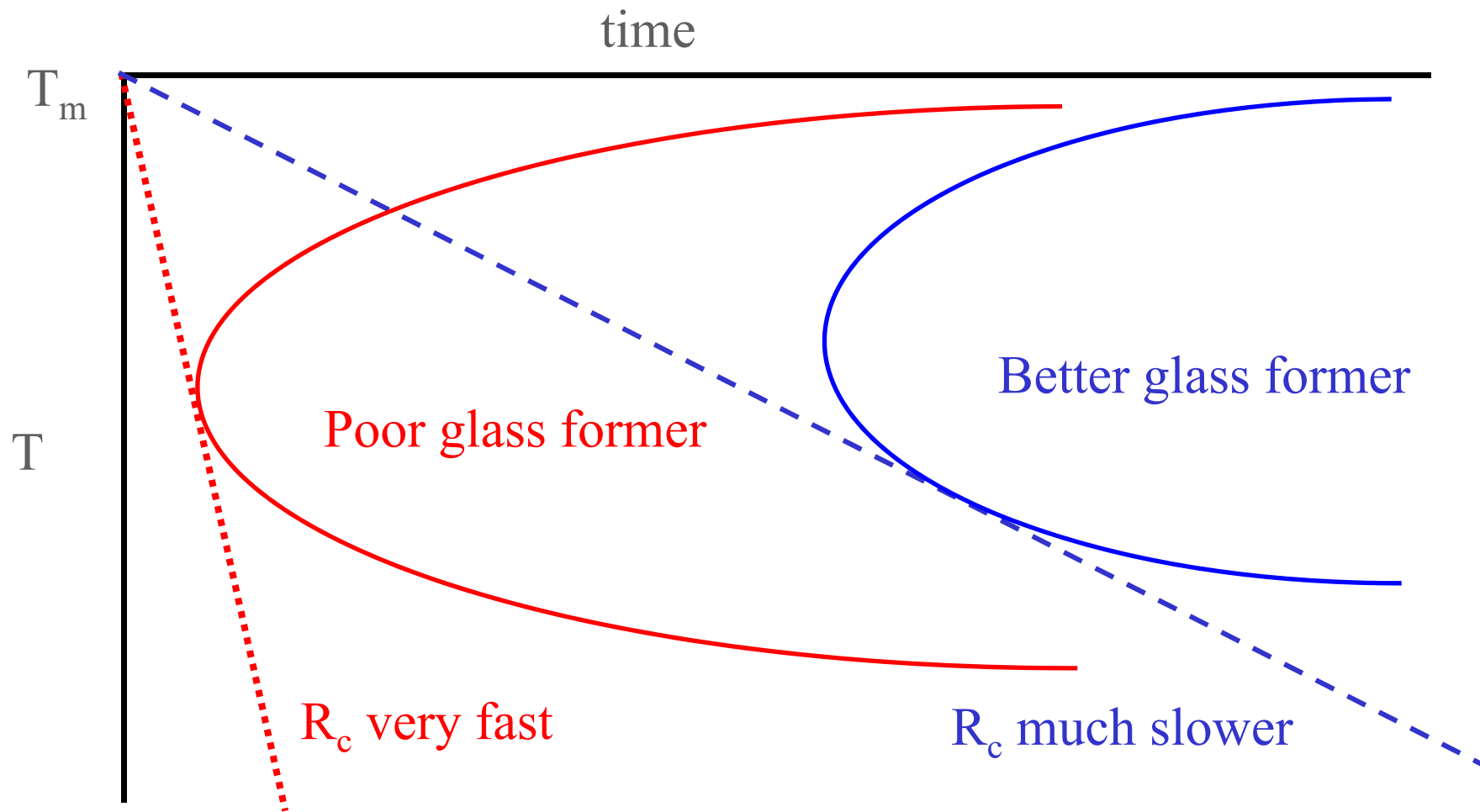


Time Transformation Curves for Silica

T-T-T Curve for Silica



TTT curves and the critical cooling rate, R_c



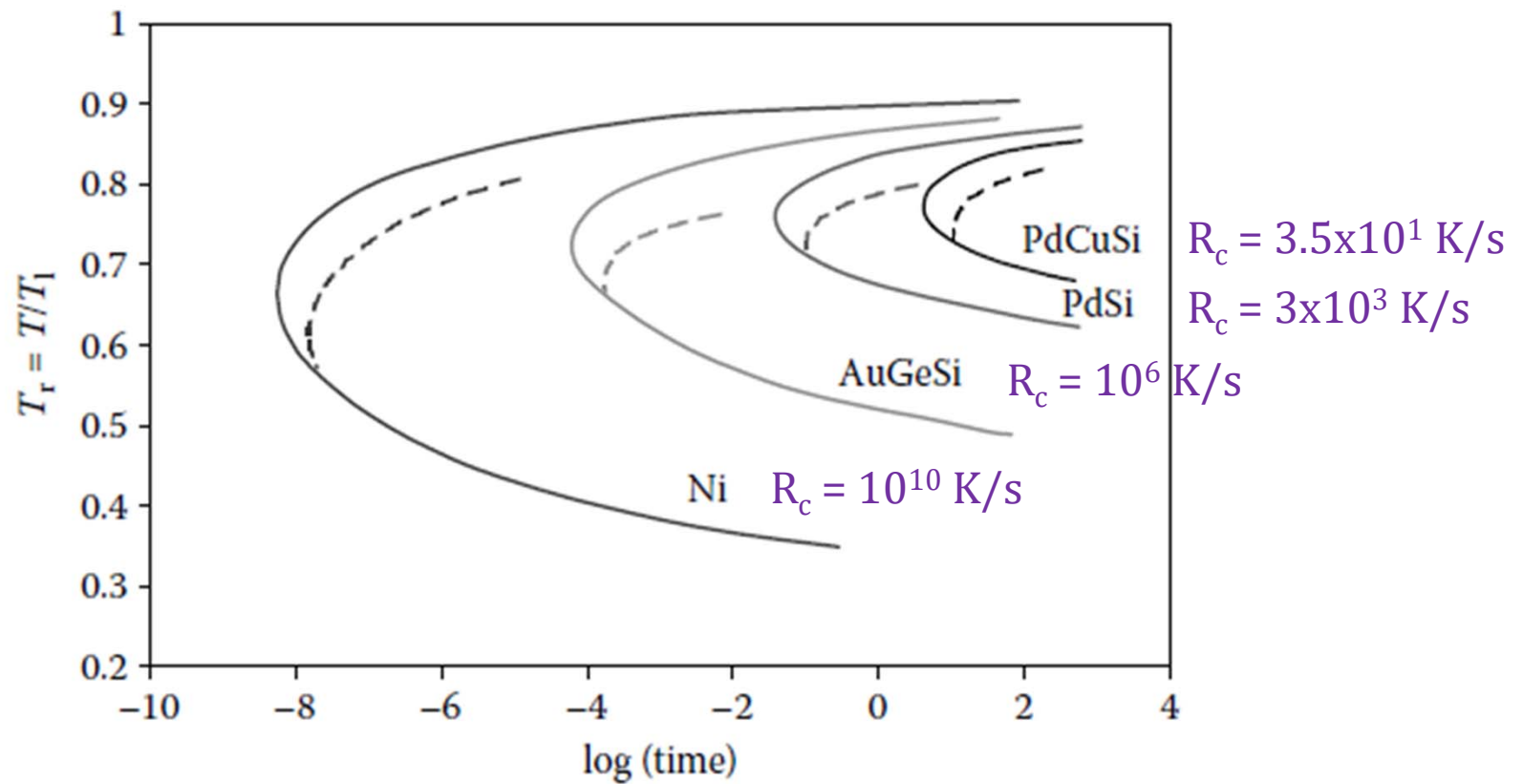


FIGURE 2.3

Time-temperature-transformation (T - T - T) curves (solid lines) and the corresponding continuous cooling transformation curves (dashed lines) for the formation of a small volume fraction for pure metal Ni, and $\text{Au}_{78}\text{Ge}_{14}\text{Si}_8$, $\text{Pd}_{82}\text{Si}_{18}$, and $\text{Pd}_{78}\text{Cu}_6\text{Si}_{16}$ alloys.

T_{rg}

1/4

1/2

2/3

Q4: Overall Transformation Kinetics–TTT diagram

“Johnson-Mehl-Avrami Equation”

5.4 Overall Transformation Kinetics – TTT Diagram

If isothermal transformation,

The fraction of Transformation as a function of Time and Temperature

$$\rightarrow f(t, T)$$

Plot f vs $\log t$.

- isothermal transformation
- $f \sim$ volume fraction of β at any time; $0 \sim 1$

Plot the fraction of transformation (1%, 99%) in T-log t coordinate.

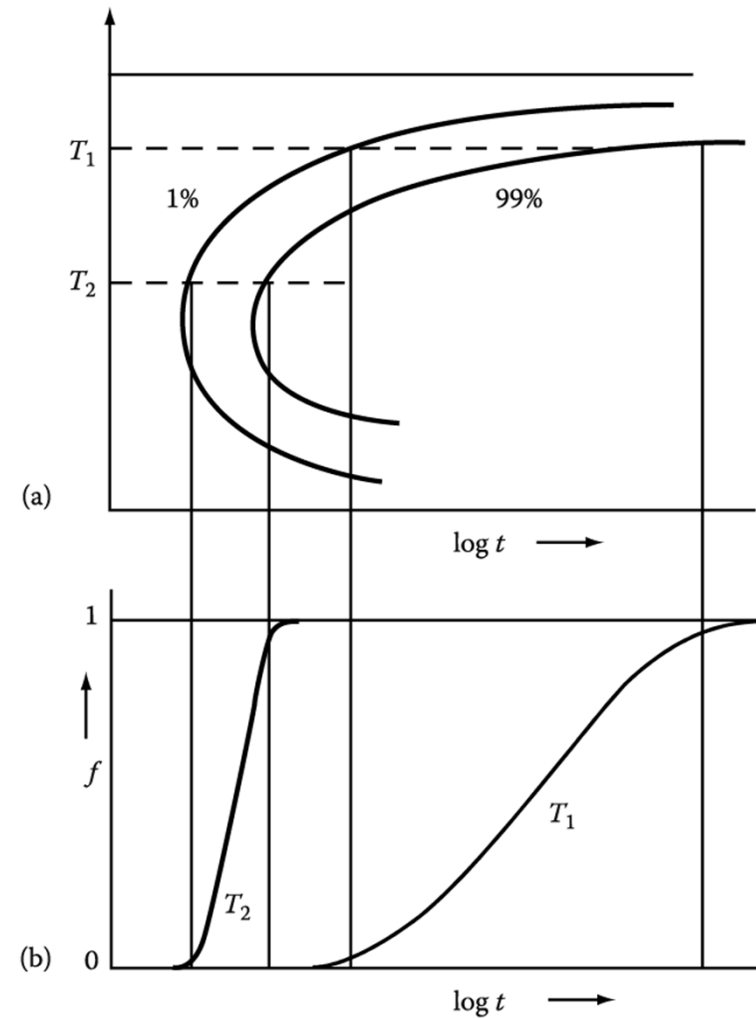
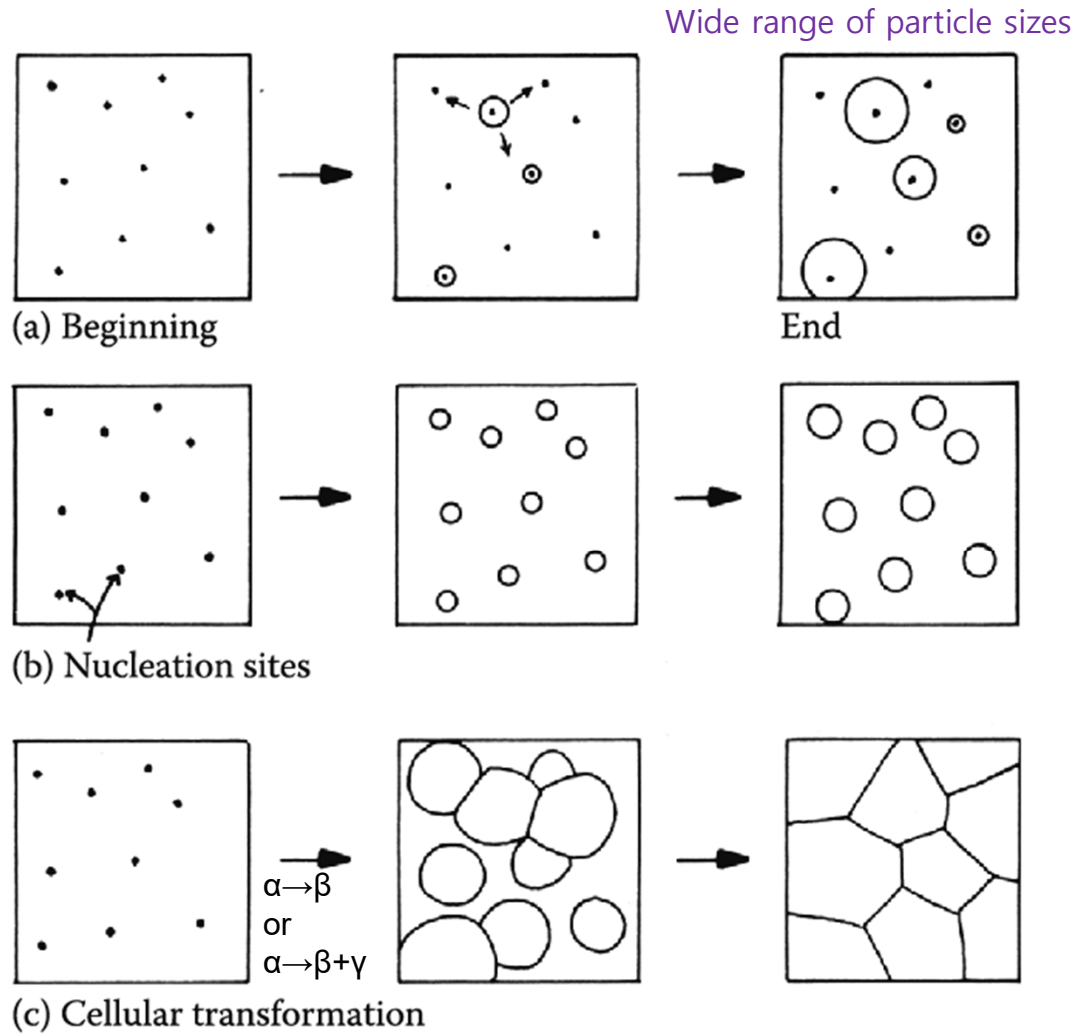


Fig. 5.23 The percentage transformation versus time for different transformation temperatures.

Influence factors for $f(t,T)$: nucleation rate, growth rate, density and distribution of nucleation sites, impingement of adjacent cells

Example,

Three Transformation Types



(a) continuous nucleation

Metastable α phase with many nucleation sites by quenching to T_t
 → f depends on the *nucleation rate and the growth rate.*

(b) all nuclei present at $t = 0$

→ f depends on the *number of nucleation sites and the growth rate.*

(c) All of the parent phase is consumed by the transformation product.

Transformation terminate by the impingement of adjacent cells growing with a constant velocity.

→ pearlite, cellular ppt, massive transformation, recrystallization



Fig. 5.24 (a) Nucleation at a constant rate during the whole transformation. (b) Site saturation – all nucleation occurs at the beginning of transformation. (c) A cellular transformation.

Transformation Kinetics

- Avrami proposed that for a three-dimensional nucleation and growth process kinetic law

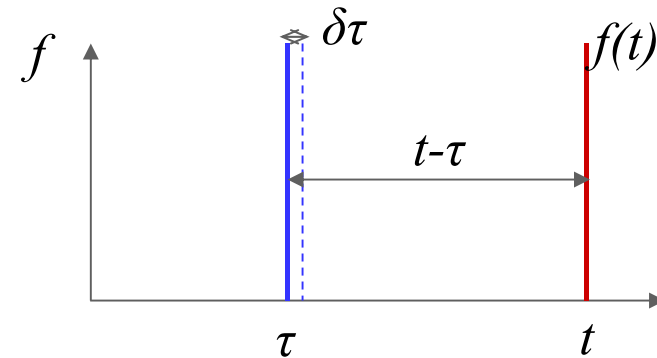
$$f = 1 - \exp(-kt^n) \quad \text{Johnson-Mehl-Avrami equation}$$

$$f: \text{volume fraction transformed} = \frac{\text{Volume of new phase}}{\text{Volume of specimen}}$$

- Assumption :
 - ✓ reaction produces by nucleation and growth
 - ✓ nucleation occurs randomly throughout specimen
 - ✓ reaction product grows rapidly until impingement

Constant Nucleation Rate Conditions

- Nucleation rate (I) is **constant**.
- Growth rate (v) is constant.
- No compositional change



$$df_e = \frac{\left(\begin{array}{l} \text{Vol. of one particle nucleated} \\ \text{during } d\tau \text{ measured at time } t \end{array} \right) \times \left(\begin{array}{l} \text{number of nuclei} \\ \text{formed during } d\tau \end{array} \right)}{\text{Volume of specimen}}$$

$$df_e = \frac{\frac{4}{3} \pi [v(t-\tau)]^3 \times (IV_0 d\tau)}{V_0}$$

$$f_e(t) = \int_0^t I \cdot \frac{4}{3} \pi [v(t-\tau)]^3 d\tau$$

$$= I \cdot \frac{4}{3} \pi v^3 \left[-\frac{1}{4} (t-\tau)^4 \right]_0^t = \frac{1}{3} \pi I v^3 t^4$$

$$V = \frac{4}{3} \pi r^3 = \frac{4}{3} \pi (vt)^3$$

$$V' = \frac{4}{3} \pi v^3 (t-\tau)^3$$

- do not consider impingement & repeated nucleation
- only true for $f \ll 1$

As time passes the β cells will eventually impinge on one another and the rate of transformation will decrease again.

Constant Nucleation Rate Conditions

- consider impingement + repeated nucleation effects

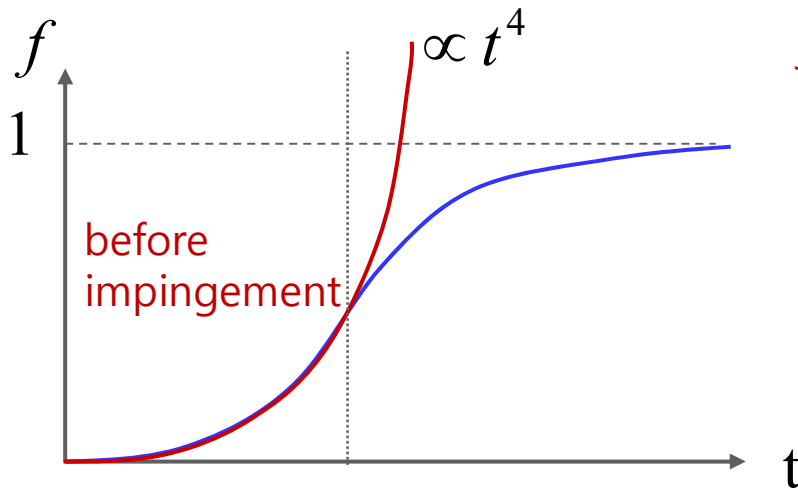
$$df = (1 - f)df_e \quad \longrightarrow \quad df_e = \frac{df}{1 - f}$$

$$f_e = -\ln(1 - f)$$

$$f(t) = 1 - \exp(-f_e(t)) = 1 - \exp\left(-\frac{\pi}{3} I v^3 t^4\right)$$

* Short time:
 $1 - \exp(z) \sim Z$ ($z \ll 1$)

* Long time:
 $t \rightarrow \infty, f \rightarrow 1$



Johnson-Mehl-Avrami Equation

$$f = 1 - \exp(-kt^n)$$

k : T sensitive $f(I, v)$ $-\frac{\pi}{3} I v^3$
 n : 1 ~ 4 (depend on nucleation mechanism)

Growth controlled.

Nucleation-controlled.

If no change of nucleation mechanism during phase transformation, n is not related to T .

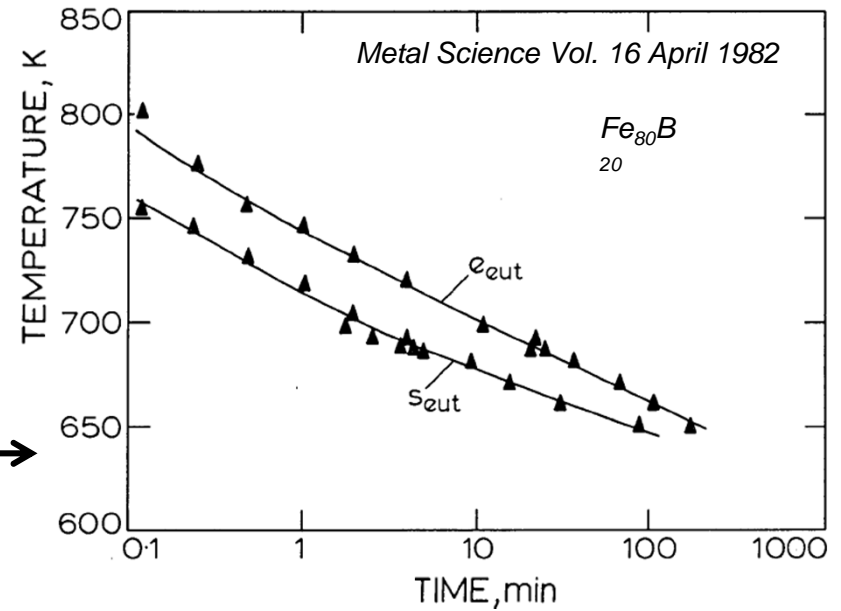
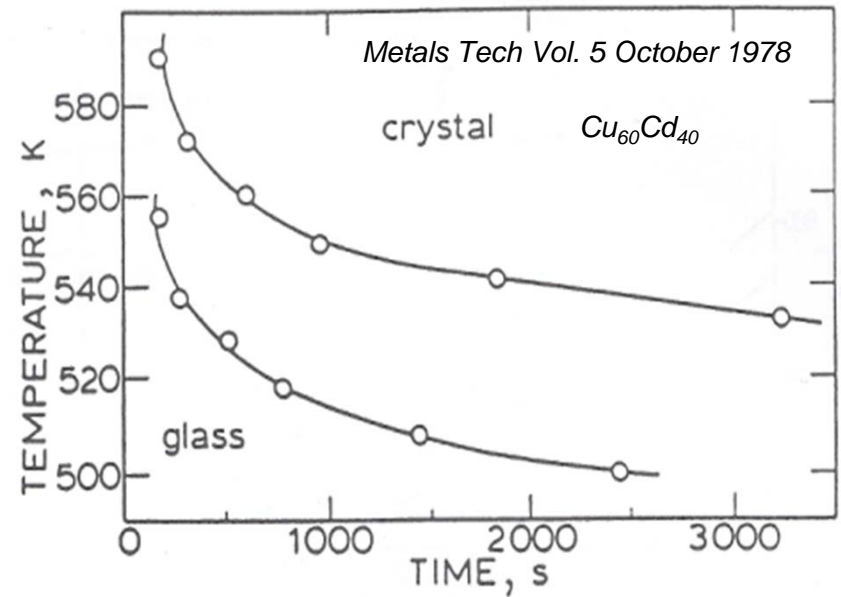
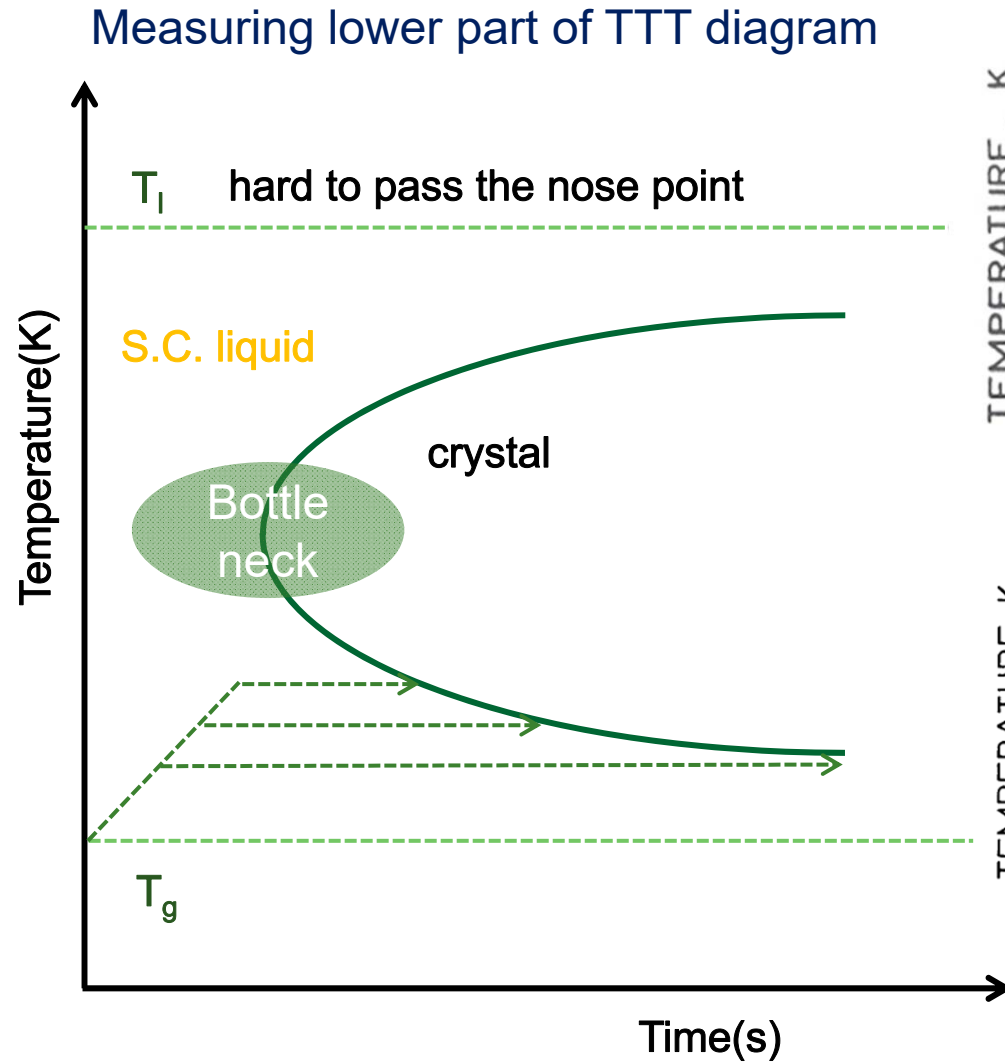
i.e. 50% transform
 $\exp(-0.7) = 0.5$

$$kt_{0.5}^n = 0.7 \quad t_{0.5} = \frac{0.7}{k^{1/n}} \quad \frac{\pi}{3} I v^3 \quad \Rightarrow \quad t_{0.5} = \frac{0.9}{N^{1/4} v^{3/4}}$$

Rapid transformations are associated with (large values of k),
 or (rapid nucleation and growth rates)

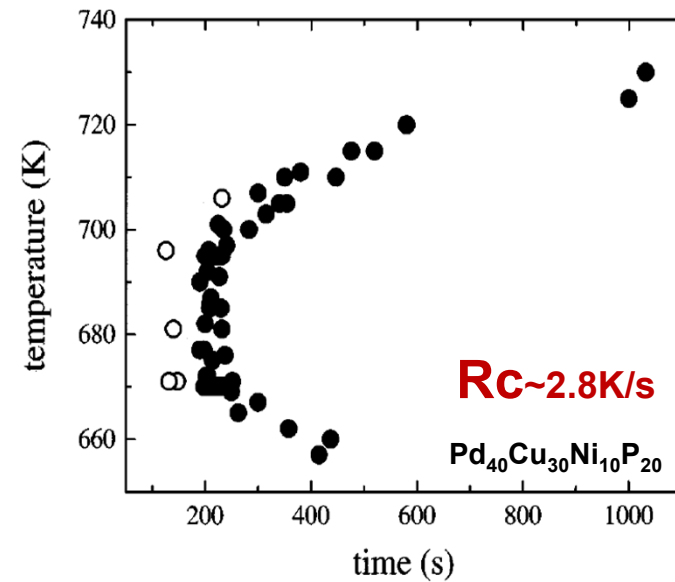
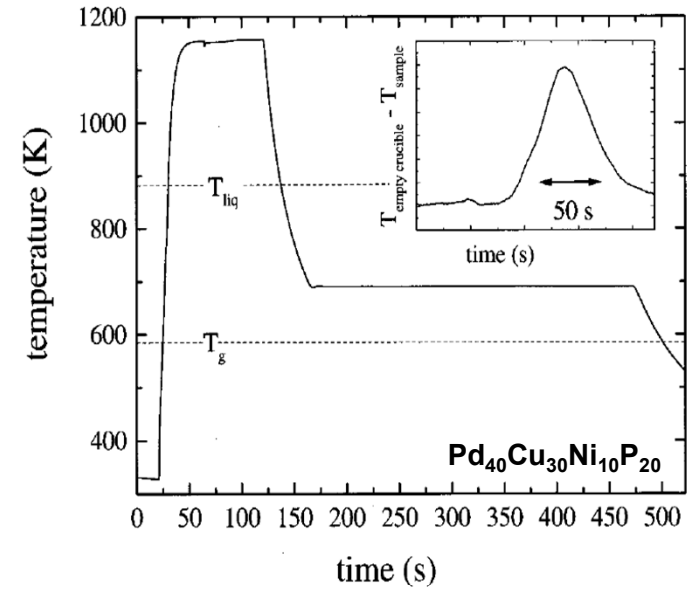
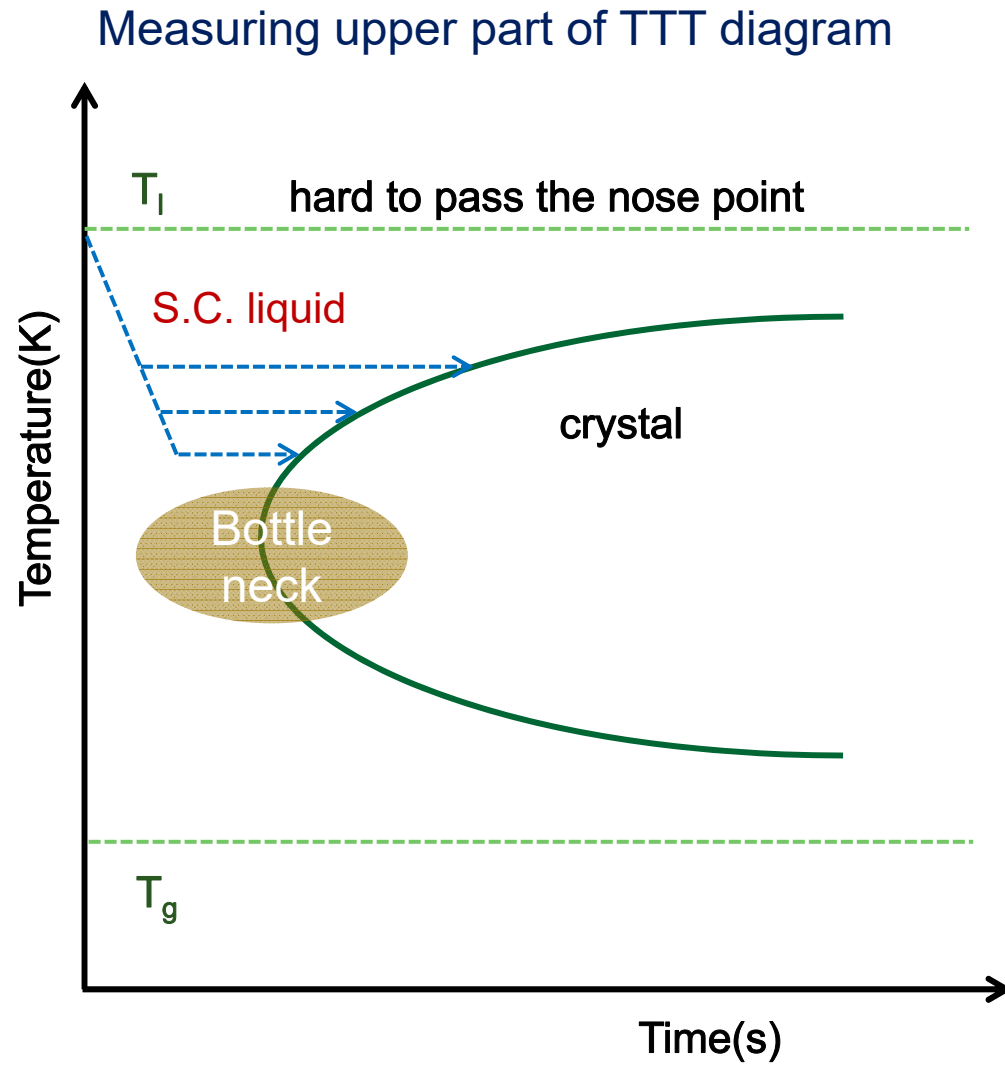
Q5: Measurement of TTT diagram

Measurement of TTT Diagram during Heating by DSC/DTA



Measurement of TTT Diagram during Heating by DSC/DTA

Appl. Phys. Lett., vol. 77, No. 8, 32 August 2000



Calculation of Time-Temperature-Transformation Diagram

Nucleation Rate

$$I = n v \exp(-NW^*/RT) \exp(-\Delta E_D/RT)$$

W^* : thermodynamic energy barrier to form nuclei

$$W^* = 16\pi\sigma^3/3(\Delta G_{\text{cryst}}(T))^2$$

$$I = n v \exp(-16\pi\sigma^3/3(\Delta G_{\text{cryst}}(T))^2/RT) \exp(-\Delta E_D/RT)$$

Growth rate

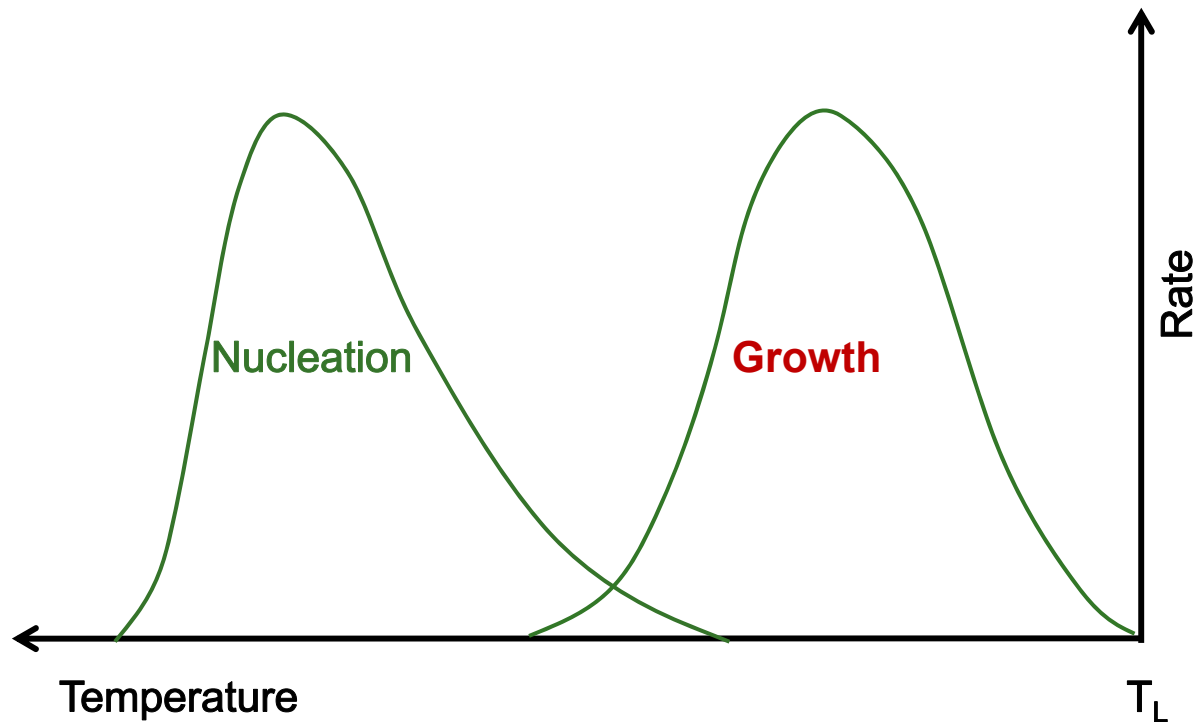
$$\mu = a v \exp(-\Delta E_D/RT) \times (1 - \exp(\Delta G_{\text{cryst}}/RT))$$

D : diffusion coefficient E_D : diffusion energy barrier to form nuclei

$$D(T) = a^2 v \exp(-\Delta E_D/RT) = fRT/3N\pi a^2 \eta(T)$$

Stokes-Einstein relation between D and η

$$\mu(T) = (fRT/3N\pi a^2 \eta(T)) (1 - \exp(\Delta G_{\text{cryst}}/RT))$$



Calculation of Time-Temperature-Transformation Diagram

Nucleation Rate

$$I = n v \exp(-N W^*/RT) \exp(-\Delta E_D/RT)$$

W^* : thermodynamic energy barrier to form nuclei

$$W^* = 16\pi\sigma^3/3(\Delta G_{\text{cryst}}(T))^2$$

$$I = n v \exp(-16\pi\sigma^3/3(\Delta G_{\text{cryst}}(T))^2/RT) \exp(-\Delta E_D/RT)$$

Growth rate

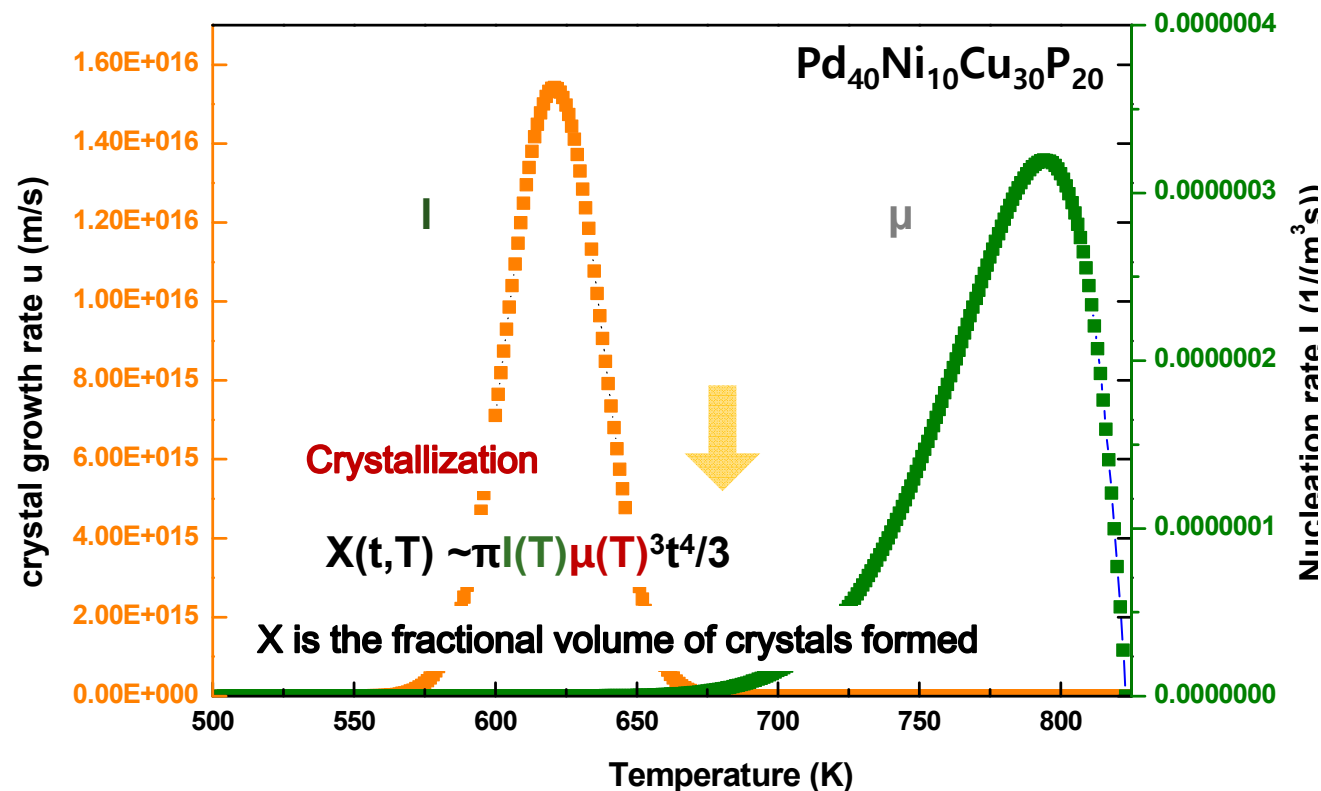
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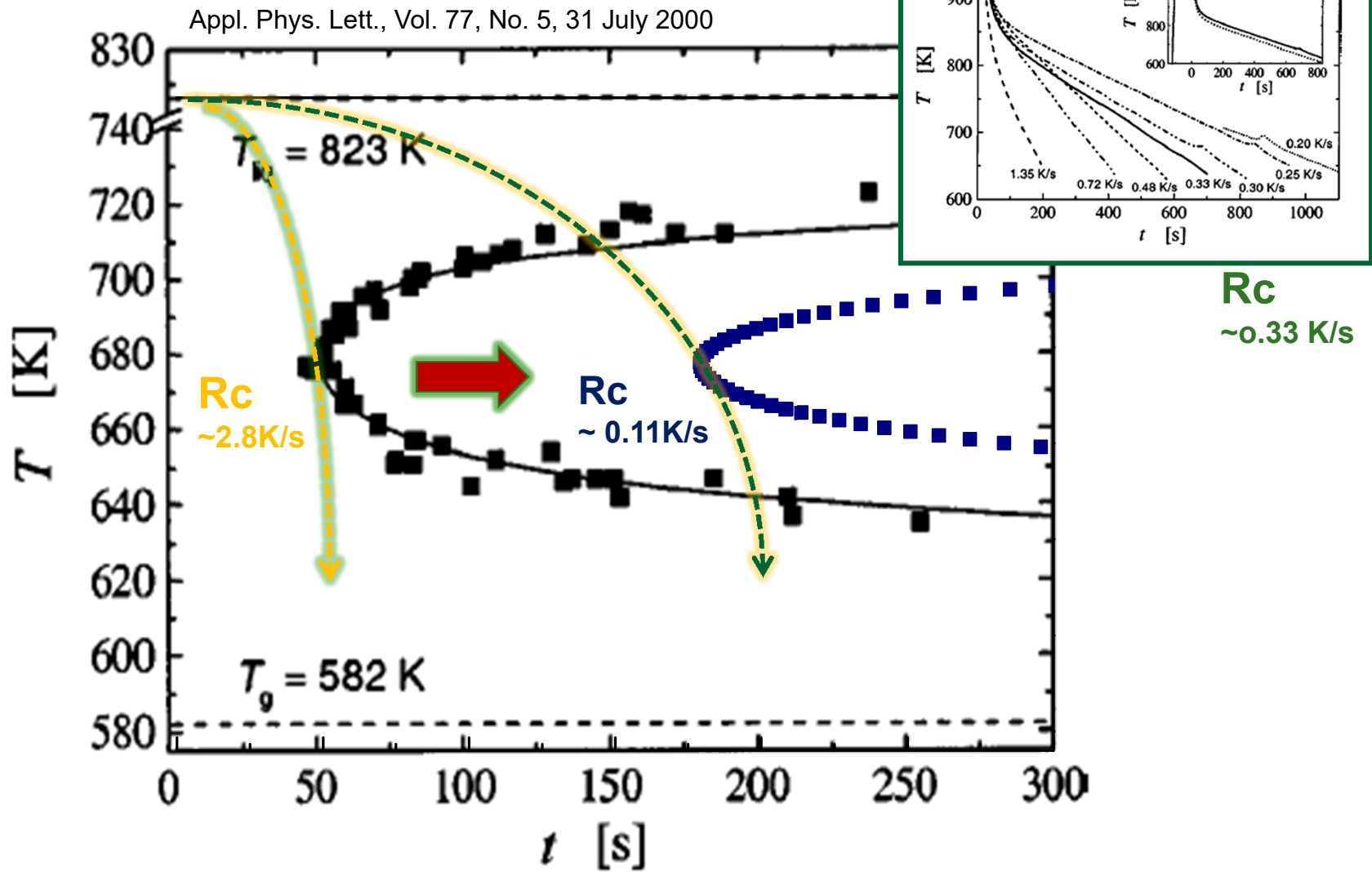
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Stokes-Einstein relation between D and η

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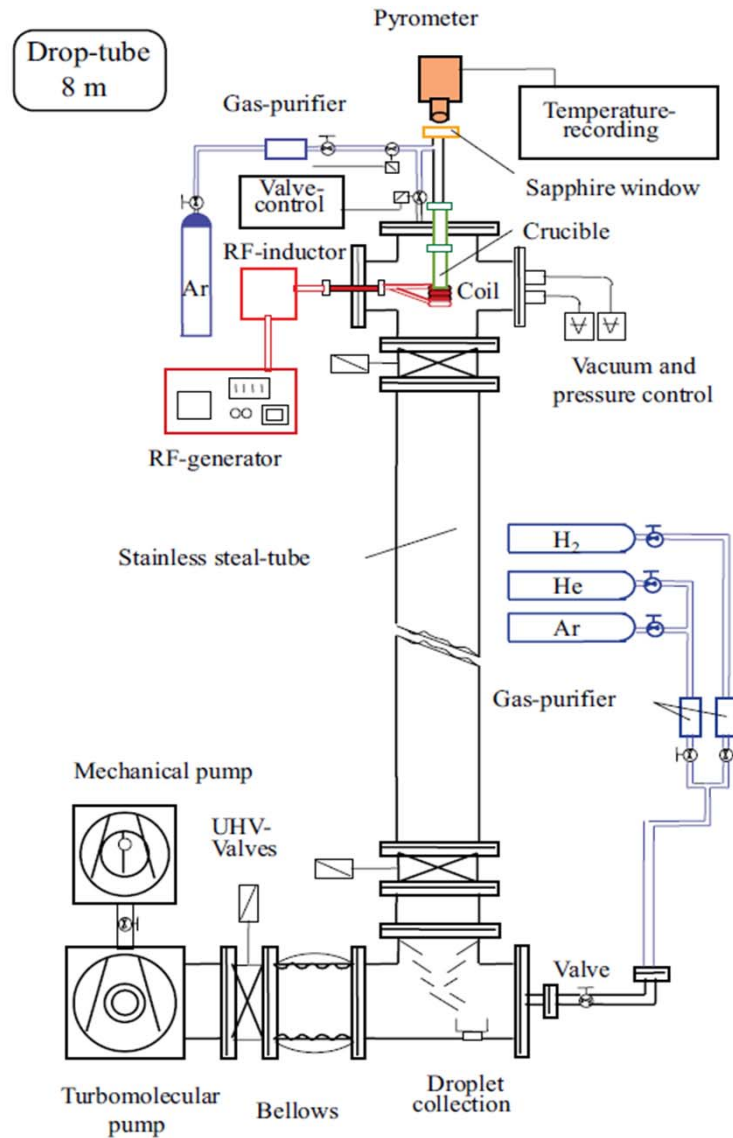


TTT Diagrams of Pd₄₀Cu₃₀Ni₁₀P₂₀



Measurement of TTT Diagram by Drop Tube Technique

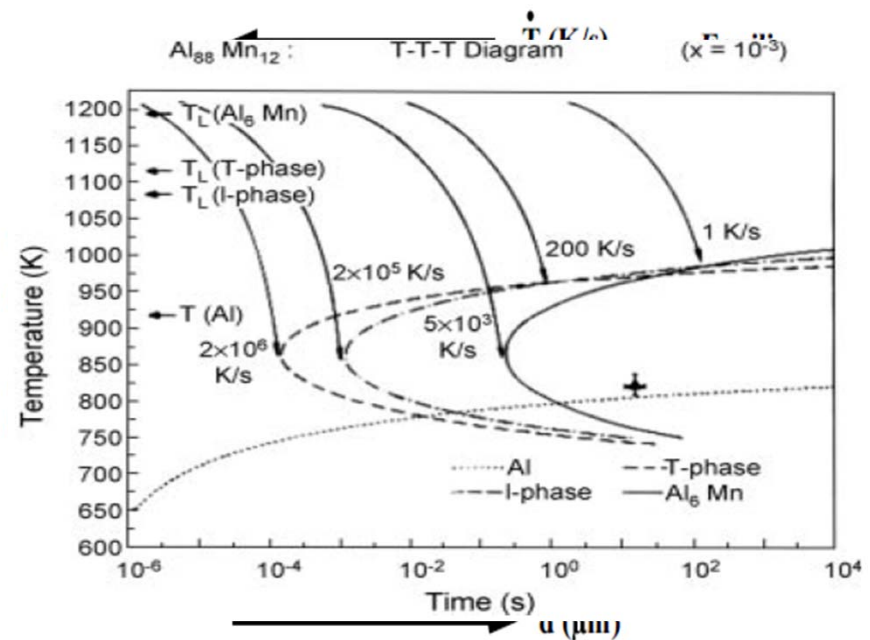
Solidification of containerless undercooled Melts, edited by Dieter M. Herlach and Douglas M. Matson, 2012, p.1-7



▶ Schematic view of DLR drop tube

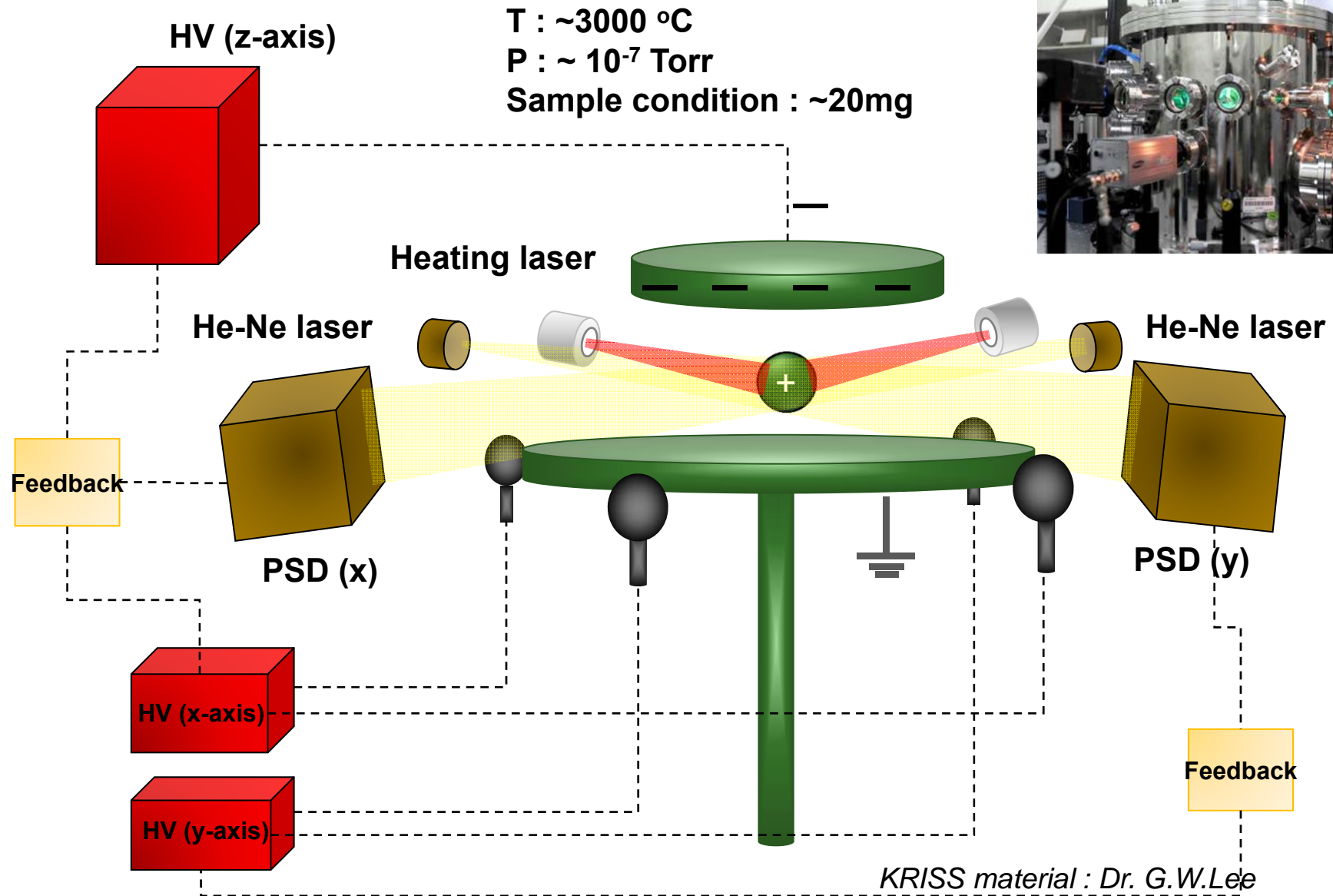
Drop tube technique

- ▶ rapid cooling of small particles by dispersion of the melt
- ▶ reduction of heterogeneous nucleation by containerless processing



▶ Phase mixture in the droplets of $Al_{88}Mn_{12}$ alloy as a function of droplet diameter

Electrostatic Levitation in KRISS



Electrostatic Levitation in KRISS

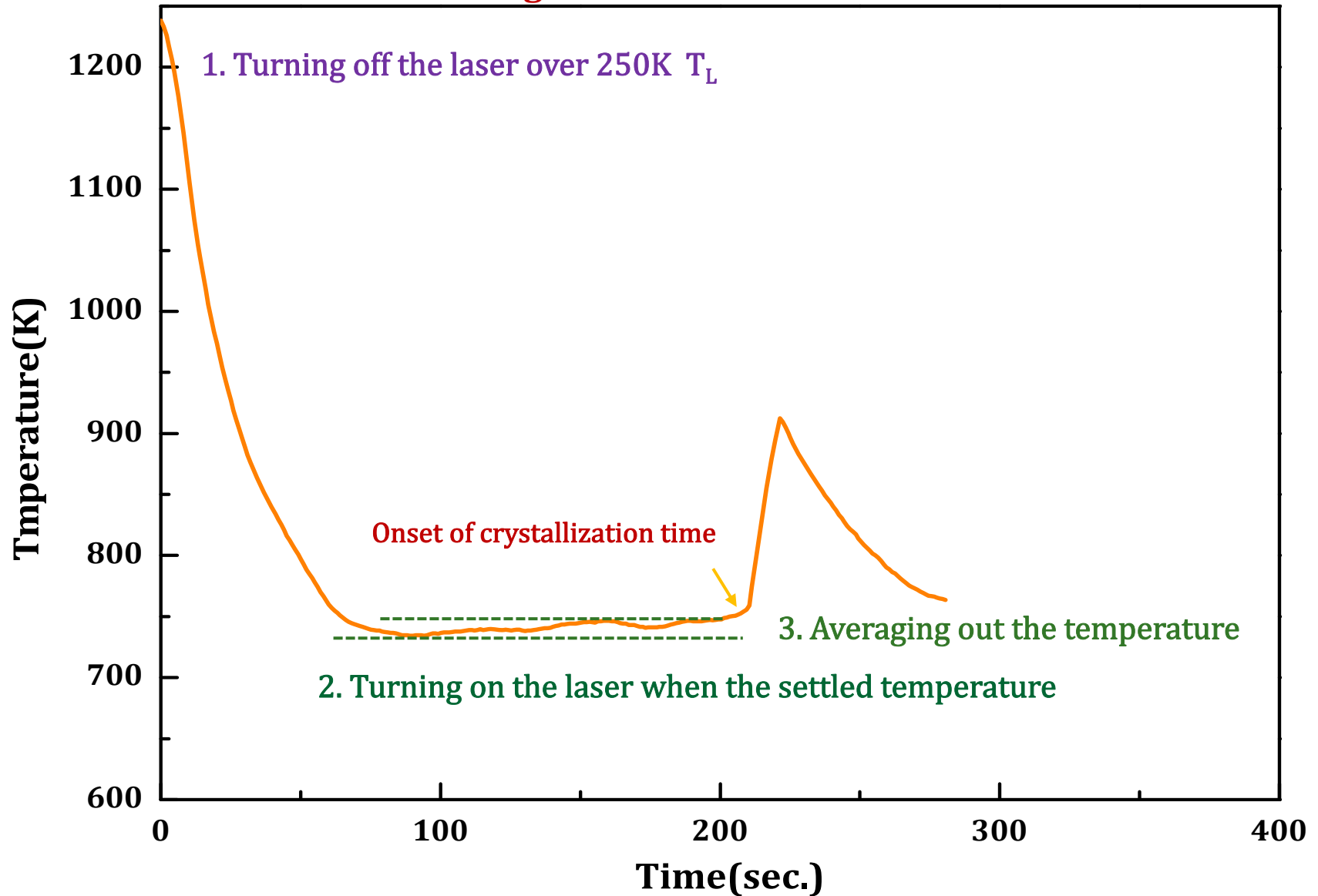


한국표준과학연구원

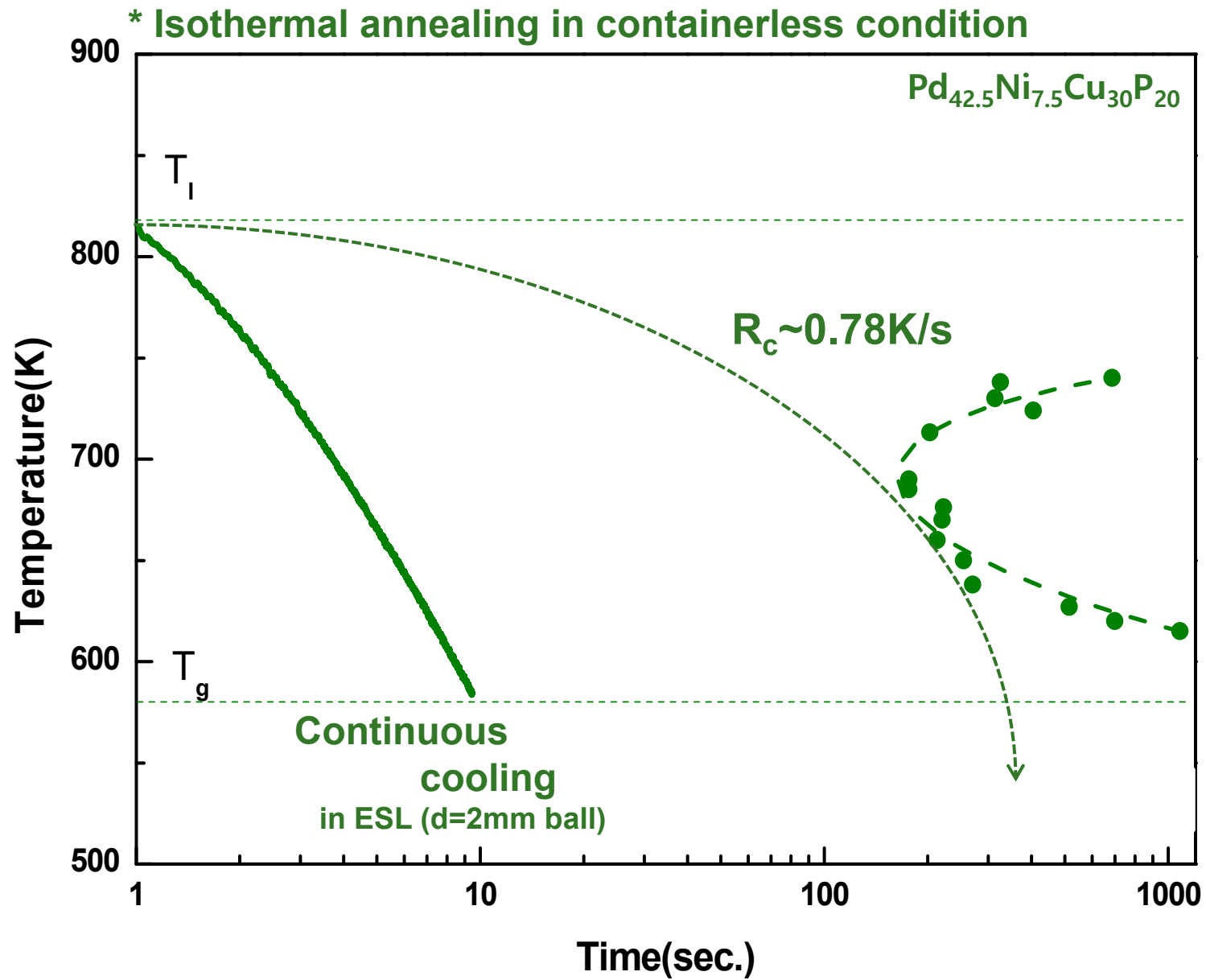
공중부양 초고온 물성 측정 기술 개발

Measurement of TTT Diagram by ESL Technique

*** Isothermal annealing in containerless condition**

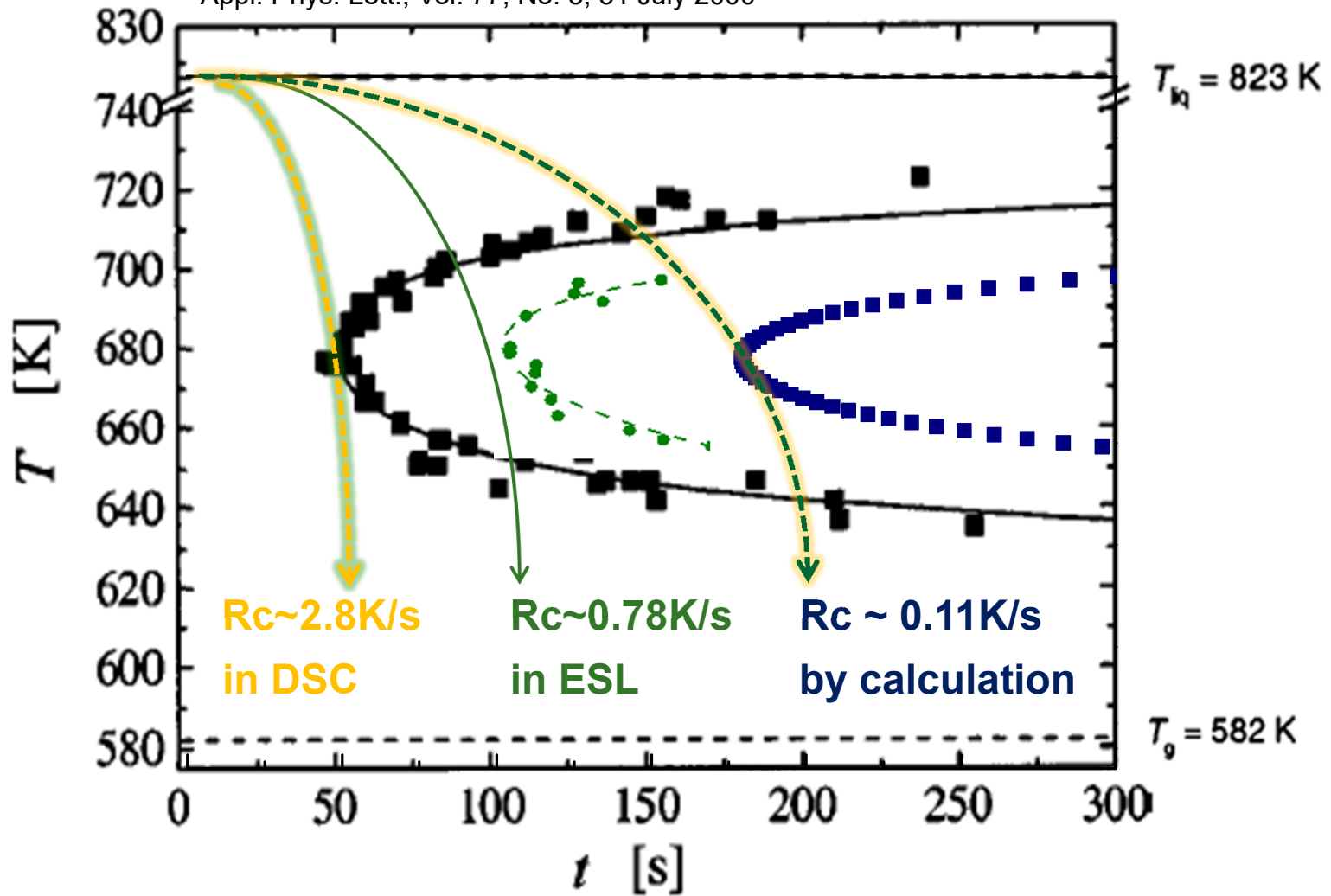


TTT Diagram of Pd_{42.5}Ni_{7.5}Cu₃₀P₂₀

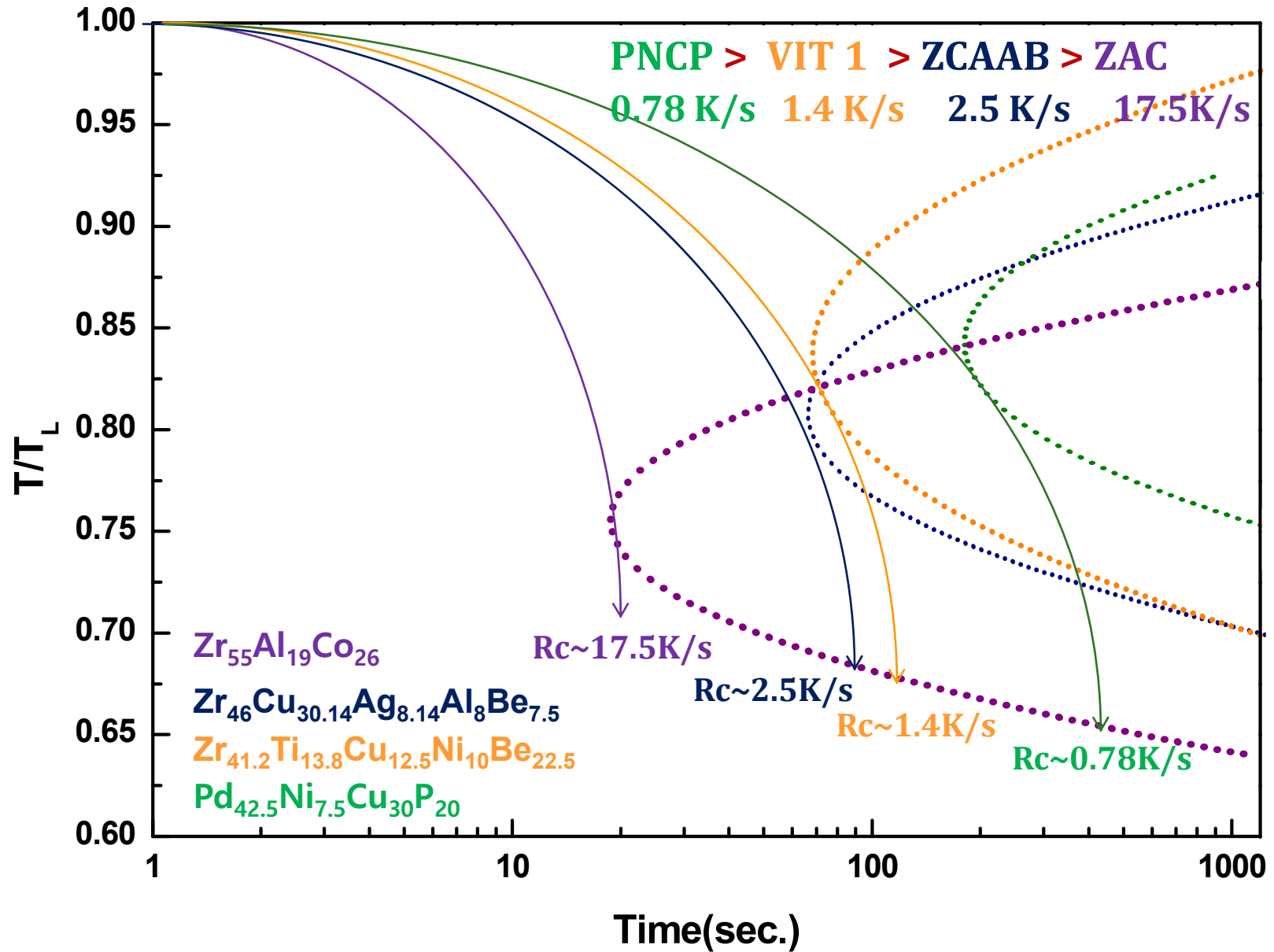


TTT Diagram of Pd₄₀Cu₃₀Ni₁₀P₂₀

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Comparison of TTT Diagrams : ZAC > ZCAAB > VIT1 > PNCP



* Time-Temperature-Transformation diagrams

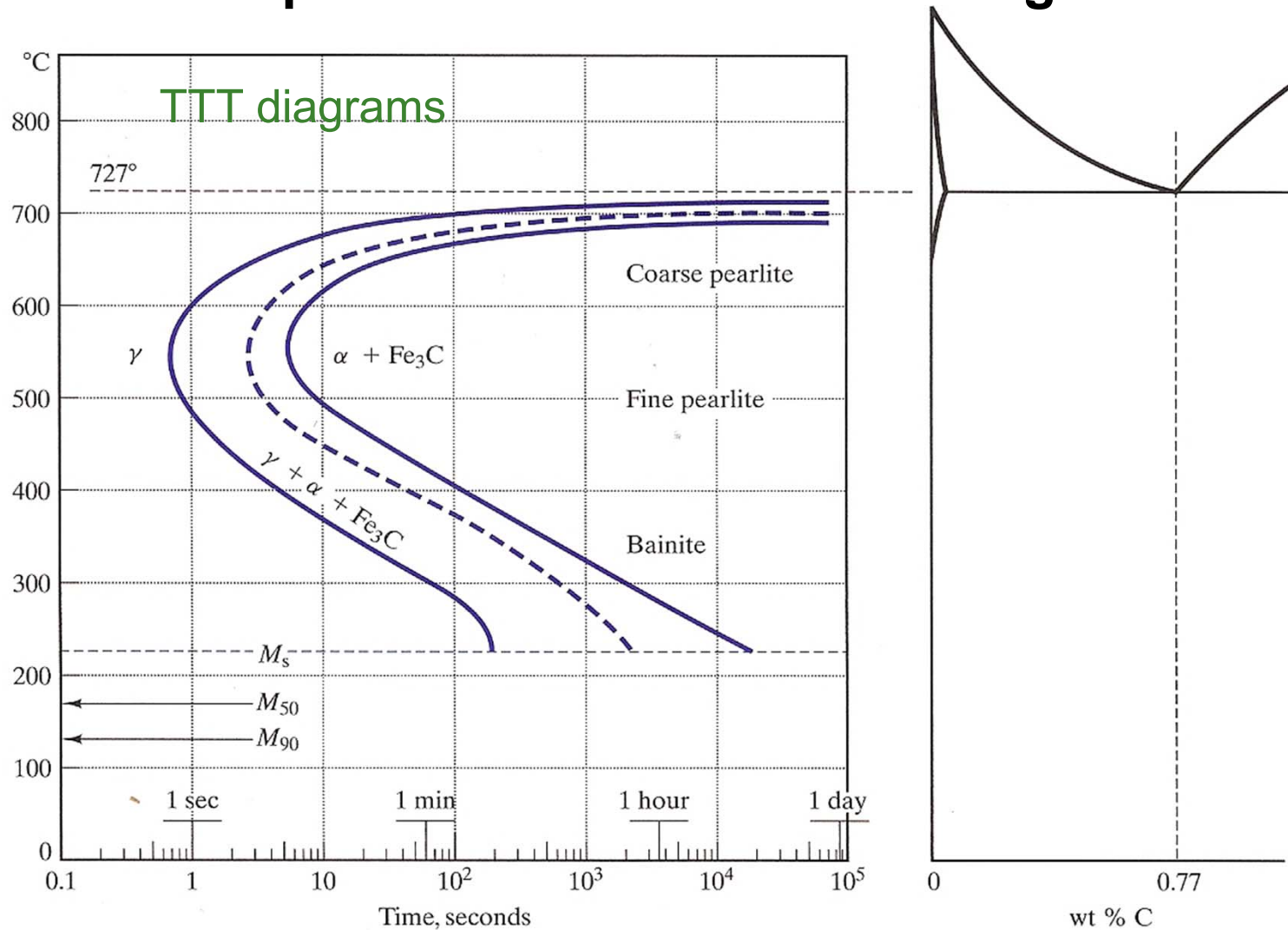


FIGURE 10.11 A more complete TTT diagram for eutectoid steel than was given in Figure 10.7. The various stages of the time-independent (or diffusionless) martensitic transformation are shown as horizontal lines. M_s represents the start, M_{50} represents 50% transformation, and M_{90} represents 90% transformation. One hundred percent transformation to martensite is not complete until a final temperature (M_f) of -46°C .

* Continuous Cooling Transformation diagrams

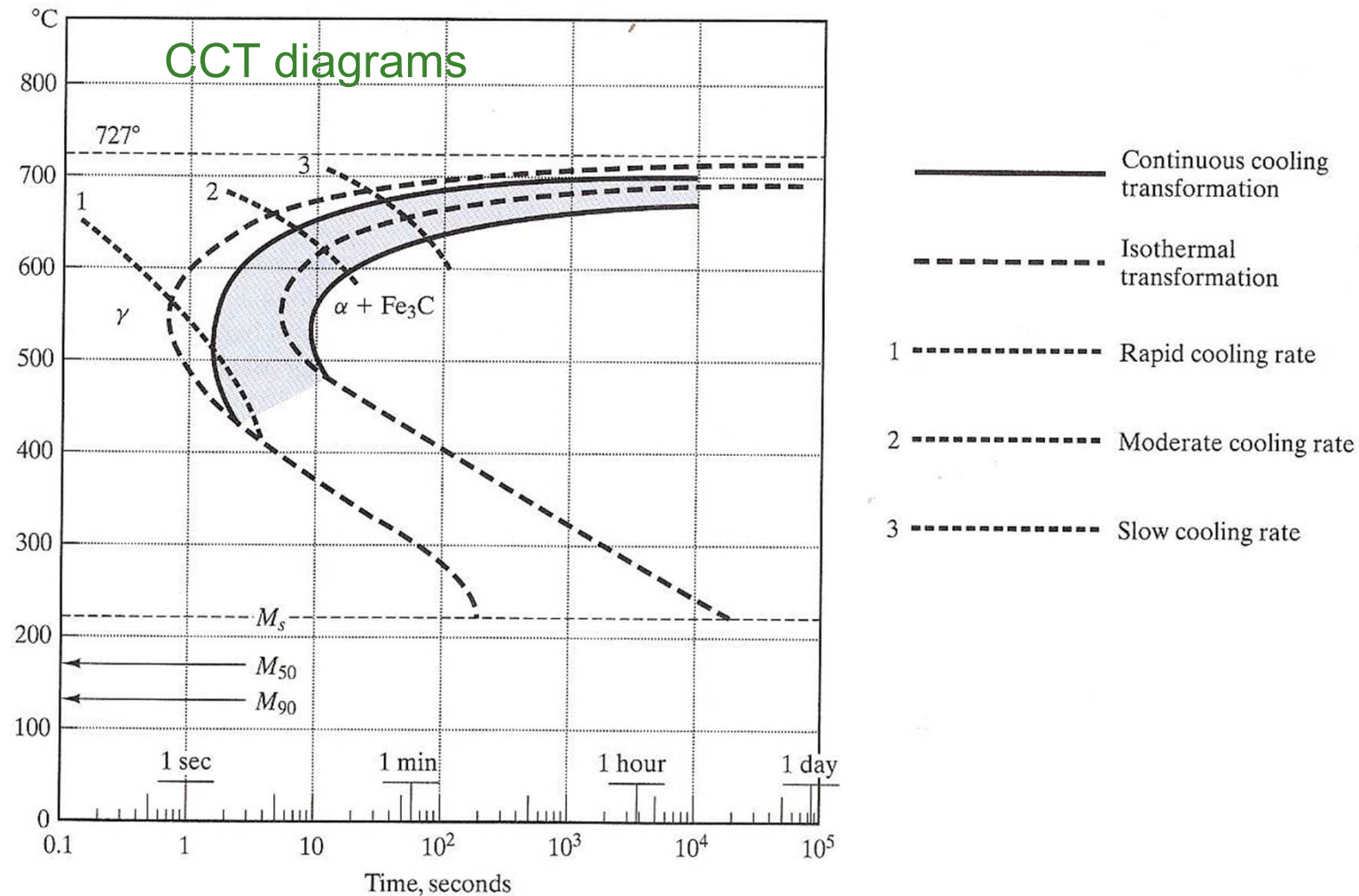


FIGURE 10.14 A continuous cooling transformation (CCT) diagram is shown superimposed on the isothermal transformation diagram of Figure 10.11. The general effect of continuous cooling is to shift the transformation curves downward and toward the right. (After Atlas of Isothermal Transformation and Cooling Transformation Diagrams, American Society for Metals, Metals Park, OH, 1977.)